

Serial EEPROM series Standard EEPROM MicroWire BUS EEPROM (3-Wire)

BR93G56-3

General Description

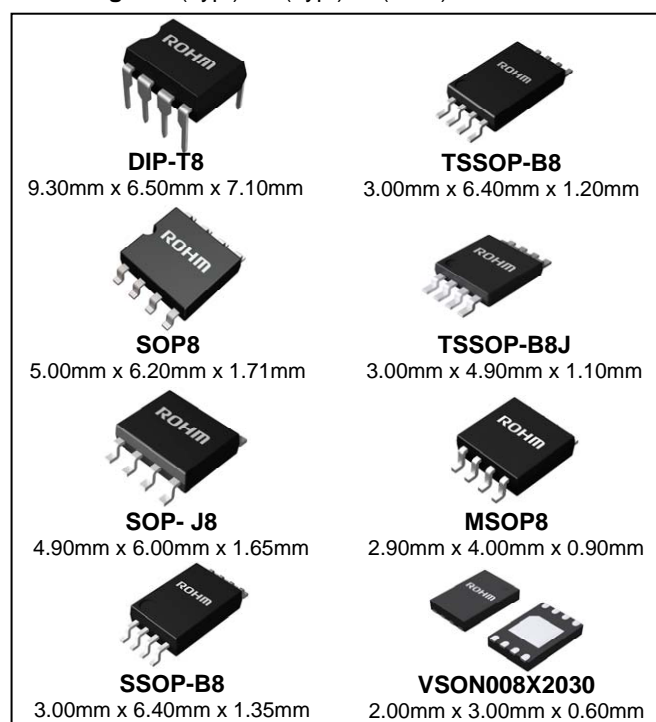
BR93G56-3 is serial EEPROM of serial 3-line Interface method.

They are dual organization (by 16bit or 8bit) and it is selected by the input of ORG PIN.

Features

- 3-line communications of chip select, serial clock, serial data input / output (the case where input and output are shared)
- Operations available at high speed 3MHz clock (4.5 V~5.5 V)
- High speed write available (write time 5ms max.)
- Same package and pin configuration from 1Kbit to 16Kbit
- 1.7~5.5V single power source operation
- Address auto increment function at read operation
- Write mistake prevention function
 - » Write prohibition at power on
 - » Write prohibition by command code
 - » Write mistake prevention function at low voltage
- Self-timed programming cycle
- Program condition display by READY / $\overline{\text{BUSY}}$
- Dual organization : by 16 bit (X16) or 8 bit (X8)
- Compact package
SOP8/SOP-J8/SSOP-B8/TSSOP-B8/MSOP8/
TSSOP-B8J/DIP-T8/VSON008X2030
- More than 40 years data retention
- More than 1 million write cycles
- Initial delivery state all addresses FFFFh (X16) or FFh (X8)

Packages W(Typ.) x D(Typ.) x H(Max.)



BR93G56-3

Capacity	Bit format	Type	Power source voltage	DIP-T8 ^{*1}	SOP8	SOP-J8	SSOP-B8	TSSOP-B8	TSSOP-B8J	MSOP8	VSON008 X2030
2Kbit	128x16 or 256x8	BR93G56-3	1.7~5.5V	●	●	●	●	●	●	●	●

^{*1} DIP-T8 is not halogen free package

●Absolute Maximum Ratings

Parameter	Symbol	Ratings	Unit	Remarks
Supply voltage	VCC	-0.3 to +6.5	V	
Permissible dissipation	Pd	800 (DIP-T8)	mW	When using at Ta=25°C or higher 8.0mW to be reduced per 1°C.
		450 (SOP8)		When using at Ta=25°C or higher 4.5mW to be reduced per 1°C.
		450 (SOP-J8)		When using at Ta=25°C or higher 4.5mW to be reduced per 1°C.
		300 (SSOP-B8)		When using at Ta=25°C or higher 3.0mW to be reduced per 1°C.
		330 (TSSOP-B8)		When using at Ta=25°C or higher 3.3mW to be reduced per 1°C.
		310 (TSSOP-B8J)		When using at Ta=25°C or higher 3.1mW to be reduced per 1°C.
		310 (MSOP8)		When using at Ta=25°C or higher 3.1mW to be reduced per 1°C.
		300 (VSON008X2030)		When using at Ta=25°C or higher 3.0mW to be reduced per 1°C.
Storage temperature	Tstg	−65 to +150	°C	
Operating temperature	Topr	−40 to +85	°C	
Input voltage/ Output voltage	-	-0.3 to Vcc+1.0	V	The Max value of Input voltage/Output voltage is not over 6.5V. When the pulse width is 50ns or less, the Min value of Input voltage/Output voltage is not under -0.8V.
Junction temperature	Tjmax	150	°C	Junction temperature at the storage condition

●Memory cell characteristics (VCC=1.7~5.5V)

Parameter	Limit			Unit	Condition
	Min.	Typ.	Max.		
Write cycles ^{*1}	1,000,000	-	-	Times	Ta=25°C
Data retention ^{*1}	40	-	-	Years	Ta=25°C

OShipment data all address FFFFh(X16) or FFh(X8)

^{*1} Not 100% TESTED

●Recommended Operation Ratings

Parameter	Symbol	Limits	Unit
Supply voltage	VCC	1.7~5.5	V
Input voltage	VIN	0~VCC	

●DC characteristics (Unless otherwise specified, VCC=1.7~5.5V, Ta=-40~+85°C)

Parameter	Symbol	Limits			Unit	Condition
		Min.	Typ.	Max.		
Input low voltage	V _{IL}	-0.3 ^{*1}	-	0.3VCC	V	1.7V ≤ VCC ≤ 5.5V
Input high voltage	V _{IH}	0.7VCC	-	VCC+1.0	V	1.7V ≤ VCC ≤ 5.5V
Output low voltage 1	V _{OL1}	0	-	0.4	V	I _{OL} =2.1mA, 2.7V ≤ VCC ≤ 5.5V
Output low voltage 2	V _{OL2}	0	-	0.2	V	I _{OL} =100μA
Output high voltage 1	V _{OH1}	2.4	-	VCC	V	I _{OH} =-0.4mA, 2.7V ≤ VCC ≤ 5.5V
Output high voltage 2	V _{OH2}	VCC-0.2	-	VCC	V	I _{OH} =-100μA
Input leakage current1	I _{LI1}	-1	-	+1	μA	V _{IN} =0V~VCC(CS,SK,DI)
Input leakage current2	I _{LI2}	-1	-	+3	μA	V _{IN} =0V~VCC(ORG)
Output leakage current	I _{LO}	-1	-	+1	μA	V _{OUT} =0V~VCC, CS=0V
Supply current	I _{CC1}	-	-	1.0	mA	VCC=1.7V, f _{SK} =1MHz, t _{EW} =5ms (WRITE)
		-	-	2.0	mA	VCC=5.5V, f _{SK} =3MHz, t _{EW} =5ms (WRITE)
	I _{CC2}	-	-	0.5	mA	f _{SK} =1MHz (READ)
		-	-	1.0	mA	f _{SK} =3MHz (READ)
	I _{CC3}	-	-	2.0	mA	VCC=2.5V, f _{SK} =1MHz t _{EW} =5ms (WRAL, ERAL)
		-	-	3.0	mA	VCC=5.5V, f _{SK} =3MHz t _{EW} =5ms (WRAL, ERAL)
Standby current	ISB1	-	-	2.0	μA	CS=0V, ORG=VCC or OPEN
	ISB2	-	-	15	μA	CS=0V, ORG=0V

*1 When the pulse width is 50ns or less, the Min value of V_{IL} is admissible to -0.8V.

●AC characteristics (Unless otherwise specified, VCC=1.7~2.5V, Ta=-40~+85°C)

Parameter	Symbol	Limits			Unit
		Min.	Typ.	Max.	
SK frequency	f _{SK}	-	-	1	MHz
SK high time	t _{SKH}	250	-	-	ns
SK low time	t _{SKL}	250	-	-	ns
CS low time	t _{CS}	250	-	-	ns
CS setup time	t _{CSS}	200	-	-	ns
DI setup time	t _{DIS}	100	-	-	ns
CS hold time	t _{CSH}	0	-	-	ns
DI hold time	t _{DIH}	100	-	-	ns
Data "1" output delay	t _{PD1}	-	-	400	ns
Data "0" output delay	t _{PD0}	-	-	400	ns
Time from CS to output establishment	t _{SV}	-	-	400	ns
Time from CS to High-Z	t _{DF}	-	-	200	ns
Write cycle time	t _{E/W}	-	-	5	ms

(Unless otherwise specified, VCC=2.5~4.5V, Ta=-40~+85°C)

Parameter	Symbol	Limits			Unit
		Min.	Typ.	Max.	
SK frequency	f _{SK}	-	-	2	MHz
SK high time	t _{SKH}	230	-	-	ns
SK low time	t _{SKL}	200	-	-	ns
CS low time	t _{CS}	200	-	-	ns
CS setup time	t _{CSS}	50	-	-	ns
DI setup time	t _{DIS}	100	-	-	ns
CS hold time	t _{CSH}	0	-	-	ns
DI hold time	t _{DIH}	100	-	-	ns
Data "1" output delay	t _{PD1}	-	-	200	ns
Data "0" output delay	t _{PD0}	-	-	200	ns
Time from CS to output establishment	t _{SV}	-	-	150	ns
Time from CS to High-Z	t _{DF}	-	-	100	ns
Write cycle time	t _{E/W}	-	-	5	ms

(Unless otherwise specified, VCC=4.5~5.5V, Ta=-40~+85°C)

Parameter	Symbol	Limits			Unit
		Min.	Typ.	Max.	
SK frequency	f _{SK}	-	-	3	MHz
SK high time	t _{SKH}	100	-	-	ns
SK low time	t _{SKL}	100	-	-	ns
CS low time	t _{CS}	200	-	-	ns
CS setup time	t _{CSS}	50	-	-	ns
DI setup time	t _{DIS}	50	-	-	ns
CS hold time	t _{CSH}	0	-	-	ns
DI hold time	t _{DIH}	50	-	-	ns
Data "1" output delay	t _{PD1}	-	-	200	ns
Data "0" output delay	t _{PD0}	-	-	200	ns
Time from CS to output establishment	t _{SV}	-	-	150	ns
Time from CS to High-Z	t _{DF}	-	-	100	ns
Write cycle time	t _{E/W}	-	-	5	ms

●Serial input / output timing

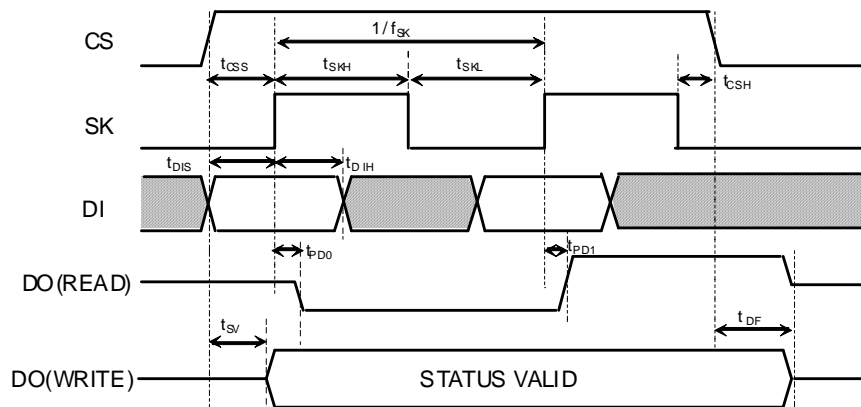


Figure 1. Sync data input / output timing

○Data is taken by DI sync with the rise of SK.

○At read operation, data is output from DO in sync with the rise of SK.

○The STATUS signal at write (READY / BUSY) is output after t_{CS} from the fall of CS after write command input, at the area DO where CS is high, and valid until the next command start bit is input. And, while CS is low, DO becomes High-Z.

○After completion of each mode execution, set CS low once for internal circuit reset, and execute the following operation mode.

○ $1/f_{SK}$ is the SK clock cycle, even if f_{SK} is maximum, the SK clock cycle can't be $t_{SKH}(\text{Min.}) + t_{SKL}(\text{Min.})$

○For "Write cycle time t_{EW} ", please see Figure 36,37,39,40.

○For "CS low time t_{CS} ", please see Figure 36,37,39,40.

●Block diagram

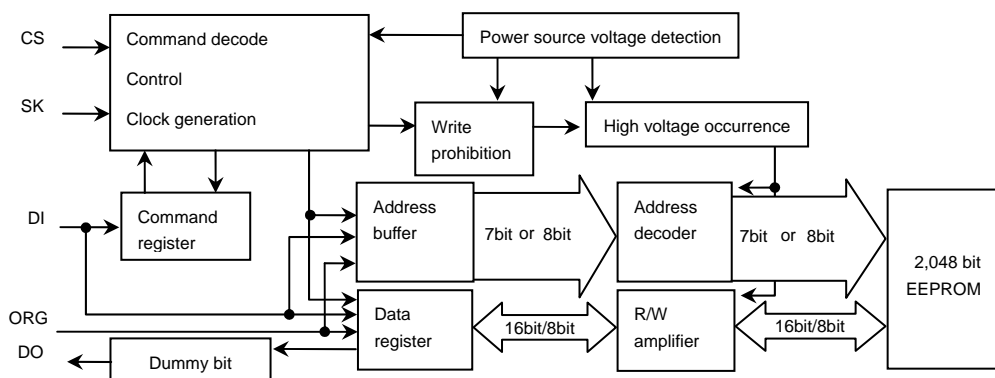


Figure 2. Block diagram

●Pin Configuration

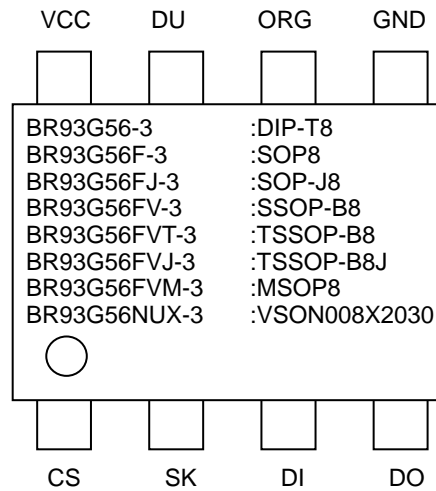


Figure 3. Pin Configuration

●Pin Descriptions

Pin name	I / O	Function
CS	Input	Chip select input
SK	Input	Serial clock input
DI	Input	Start bit, ope code, address, and serial data input
DO	Output	Serial data output, READY / $\overline{\text{BUSY}}$ STATUS display output
GND	-	All input / output reference voltage, 0V
ORG	Input	Organization select, X16mode or X8 mode ^{*1}
DU	-	Don't use terminal ^{*2}
VCC	-	Supply voltage

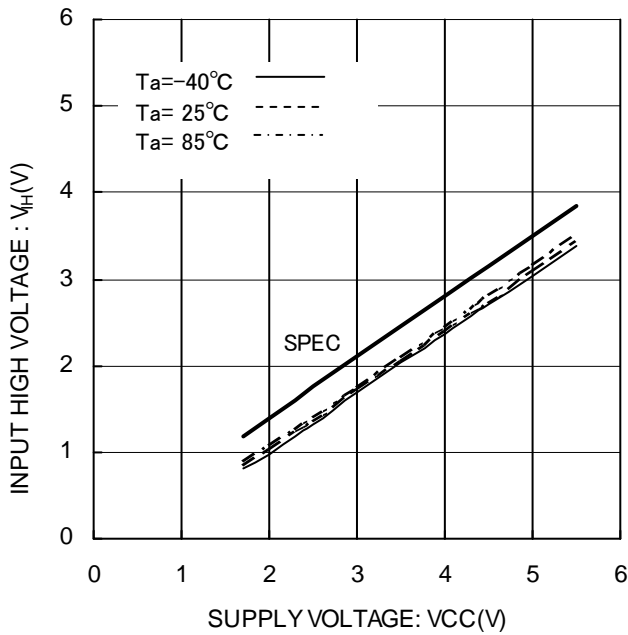
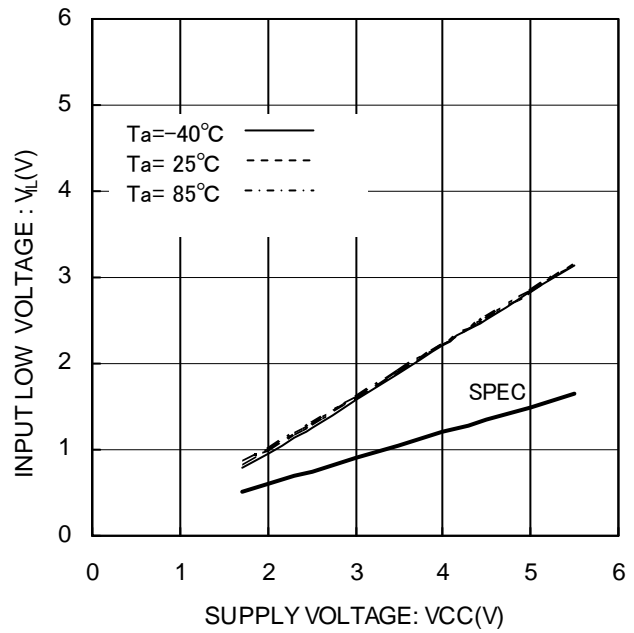
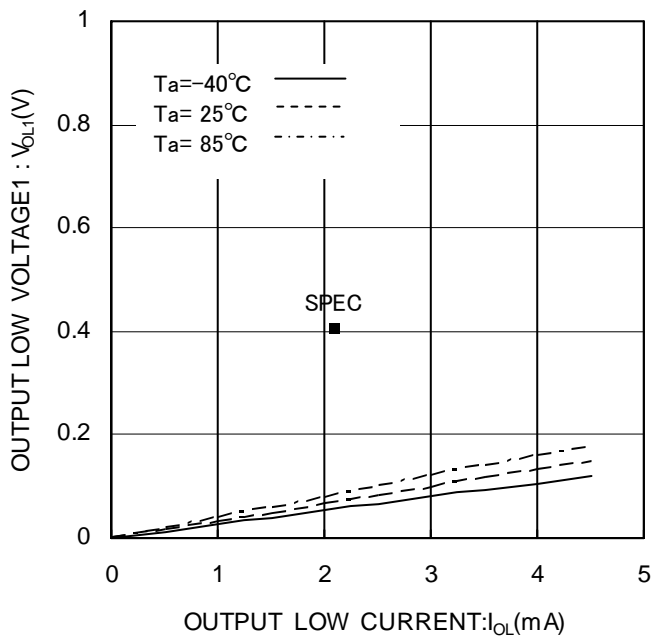
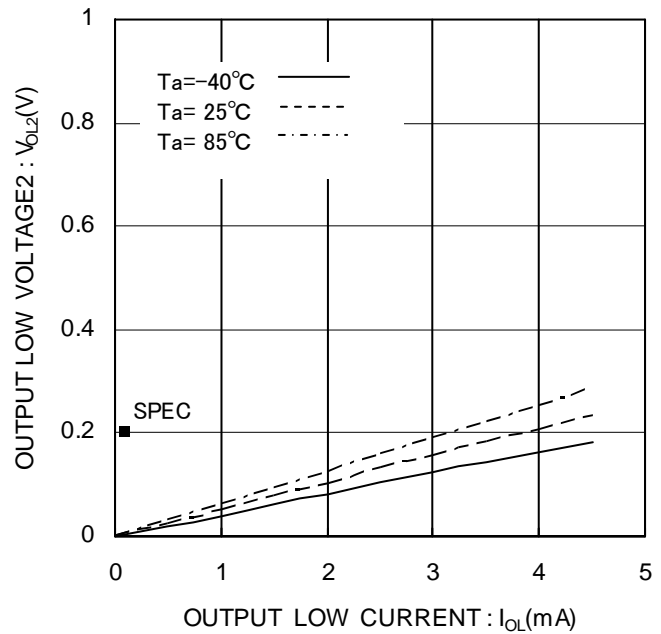
^{*1} The memory array organization may be divided into either X8 or X16 which is selected by pin ORG.

When ORG is OPEN or connected to VCC, X16 organization is selected.

When ORG is connected to ground, X8 organization is selected.

^{*2} Terminals not used may be set to any of high, low, and OPEN

● Typical Performance Curves

Figure 4. Input high voltage V_{IH} (CS,SK,DI,ORG)Figure 5. Input low voltage V_{IL} (CS,SK,DI,ORG)Figure 6. Output low voltage1 V_{OL1} ($V_{CC} = 2.7\text{V}$)Figure 7. Output low voltage2 V_{OL2} ($V_{CC} = 1.7\text{V}$)

● Typical Performance Curves - Continued

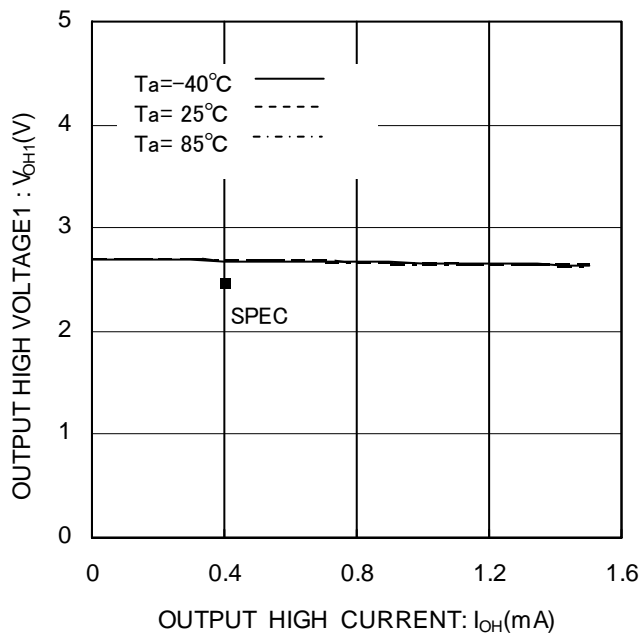


Figure 8. Output high voltage1 V_{OH1} ($V_{CC}=2.7V$)

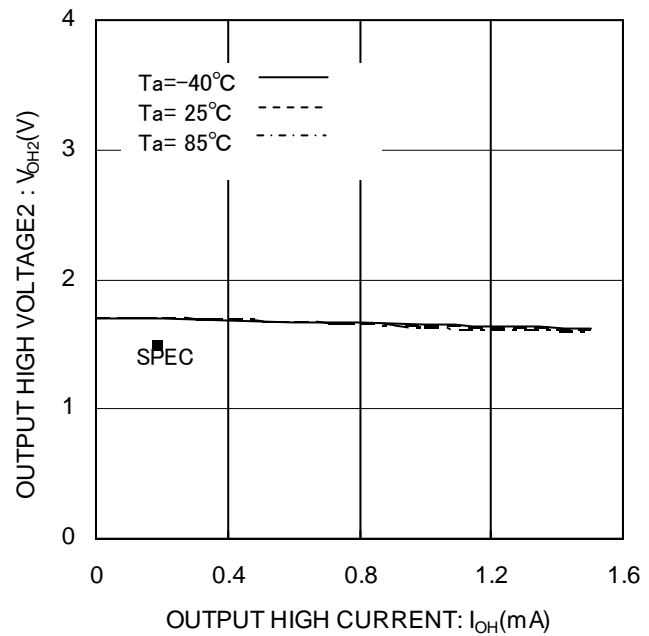


Figure 9. Output high voltage2 V_{OH2} ($V_{CC}=1.7V$)

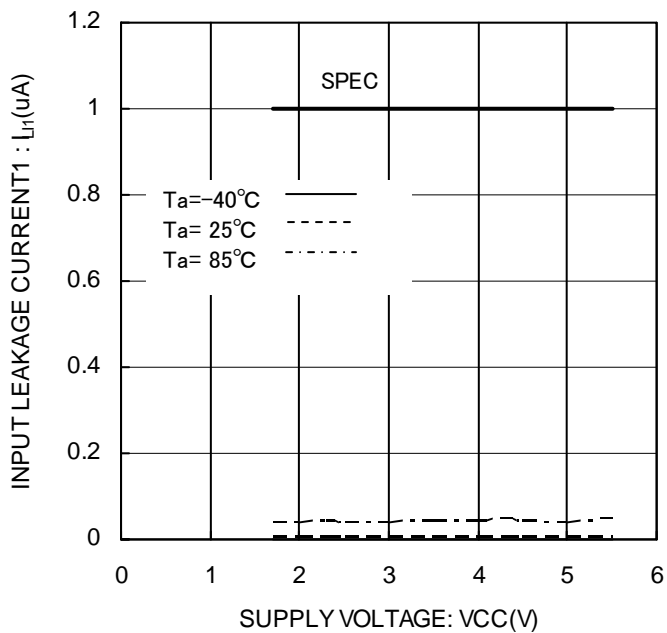


Figure 10. Input leakage current1 I_{L1} (CS, SK, DI)

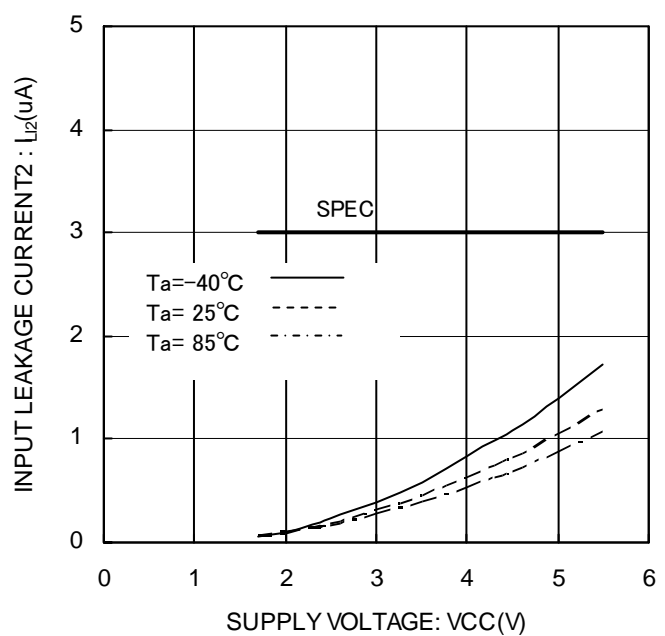


Figure 11. Input leakage current2 I_{L2} (ORG)

● Typical Performance Curves - Continued

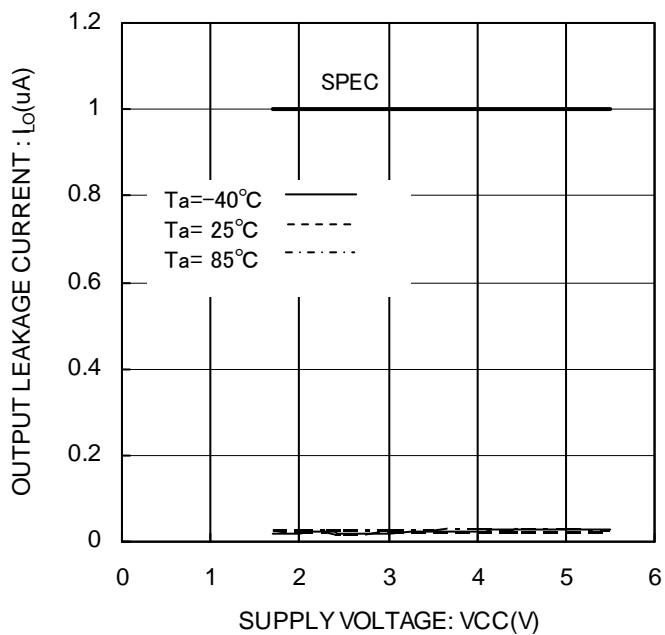


Figure 12. Output leakage current $I_{LO}(DO)$

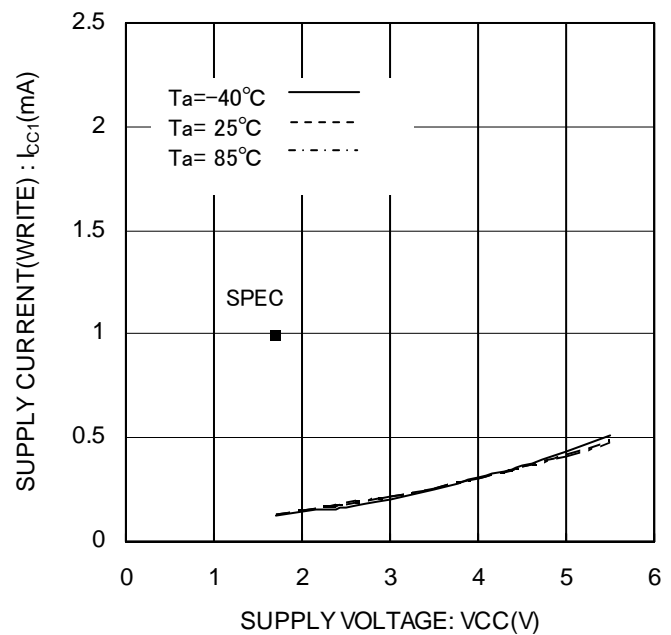


Figure 13. Supply current (WRITE)
 $I_{CC1}(WRITE, f_{SK}=1MHz)$

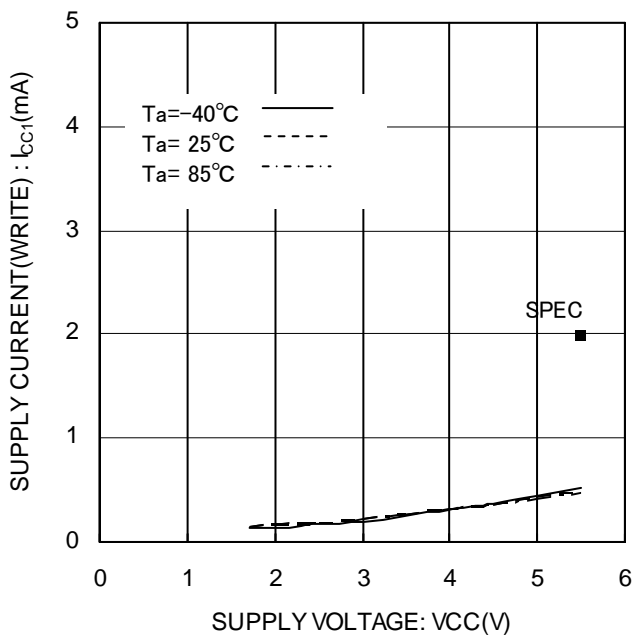


Figure 14. Supply current (WRITE)
 $I_{CC1}(WRITE, f_{SK}=3MHz)$

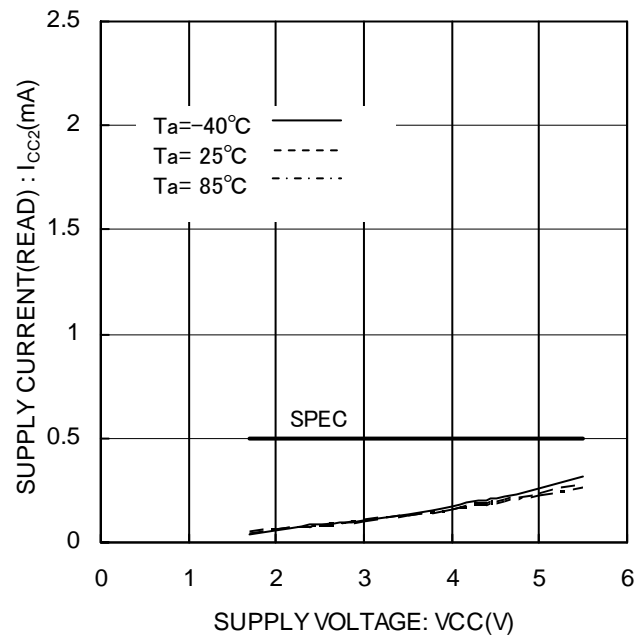


Figure 15. Supply current (READ)
 $I_{CC2}(READ, f_{SK}=1MHz)$

● Typical Performance Curves - Continued

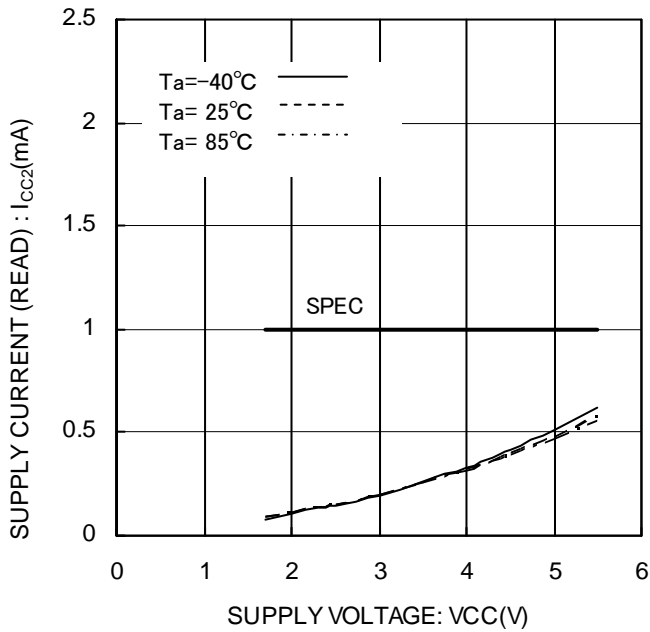


Figure 16. Supply current (READ)
 $I_{CC2}(\text{READ}, f_{SK}=3\text{MHz})$

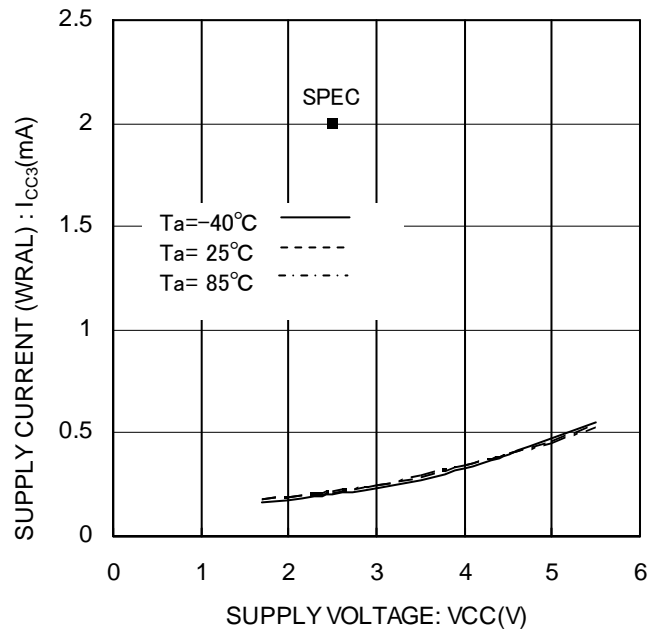


Figure 17. Supply current (WRAL)
 $I_{CC3}(\text{WRAL}, f_{SK}=1\text{MHz})$

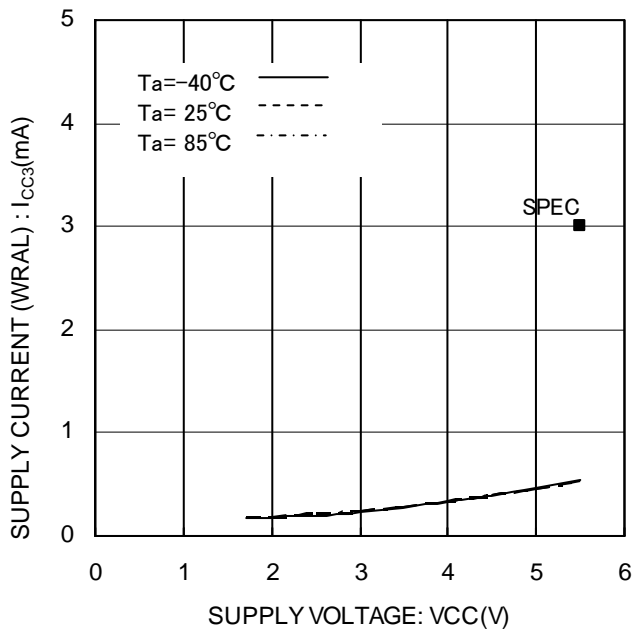


Figure 18. Supply current (WRAL)
 $I_{CC3}(\text{WRAL}, f_{SK}=3\text{MHz})$

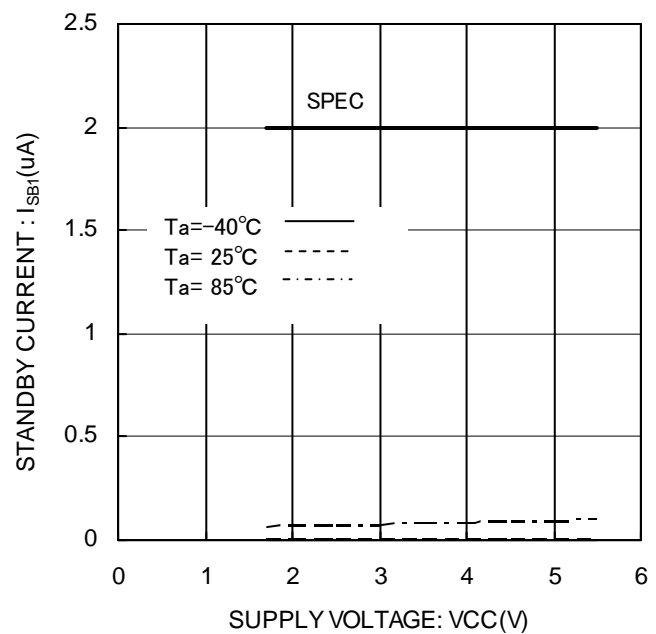
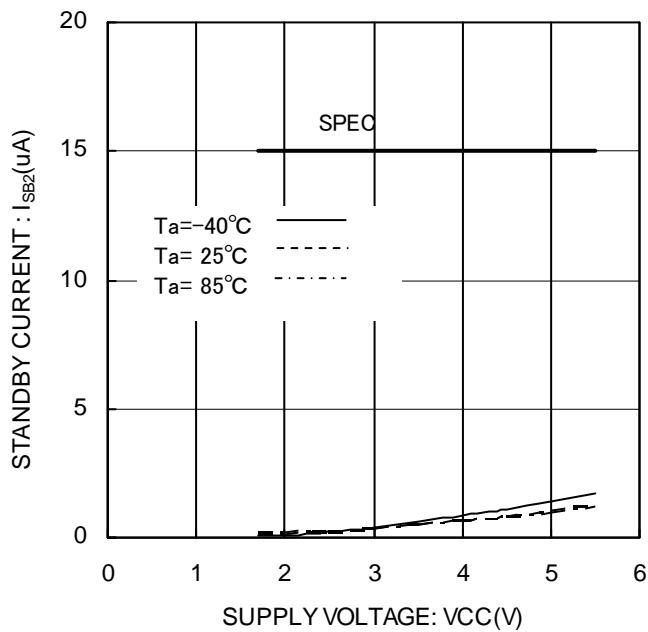
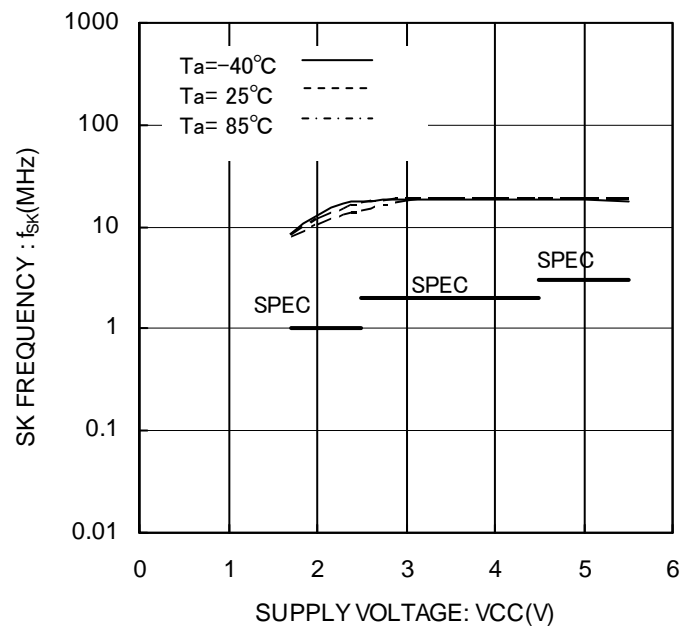
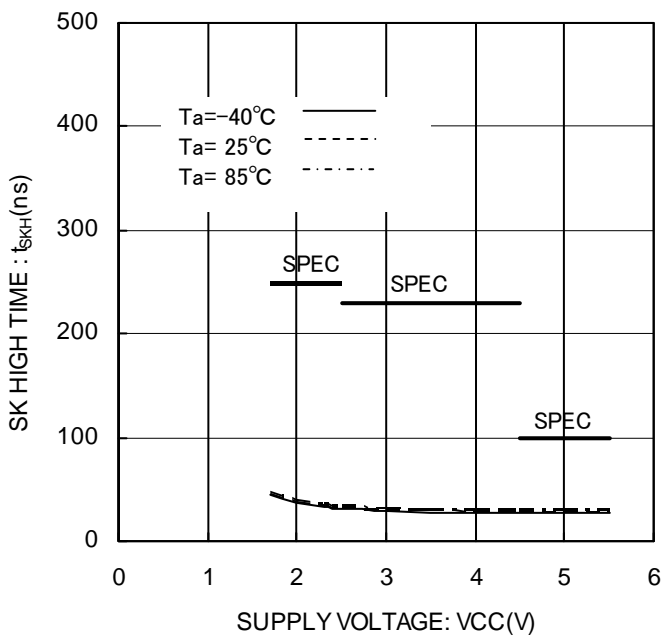
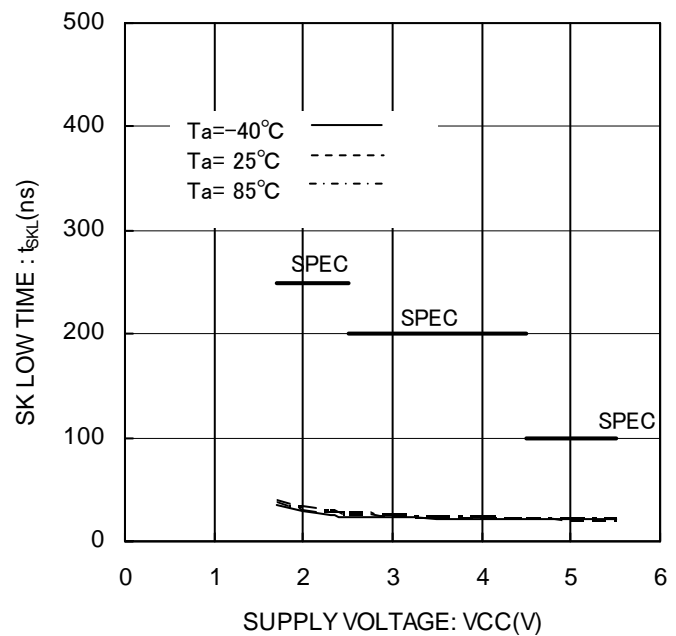
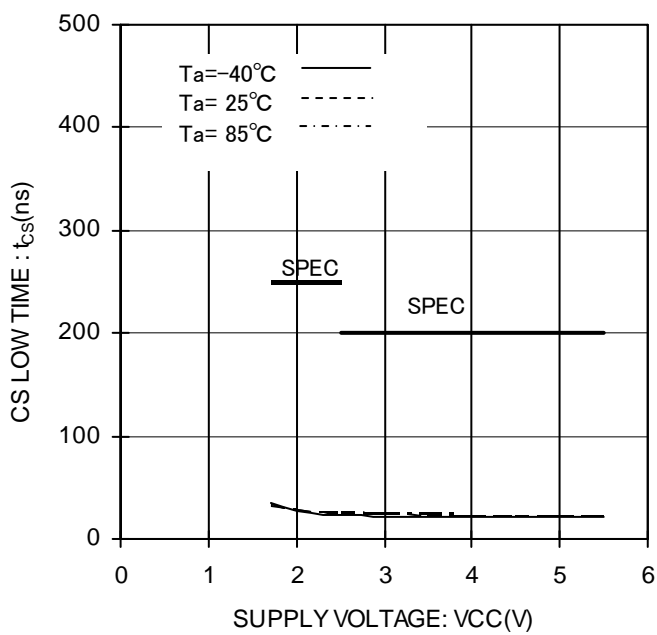
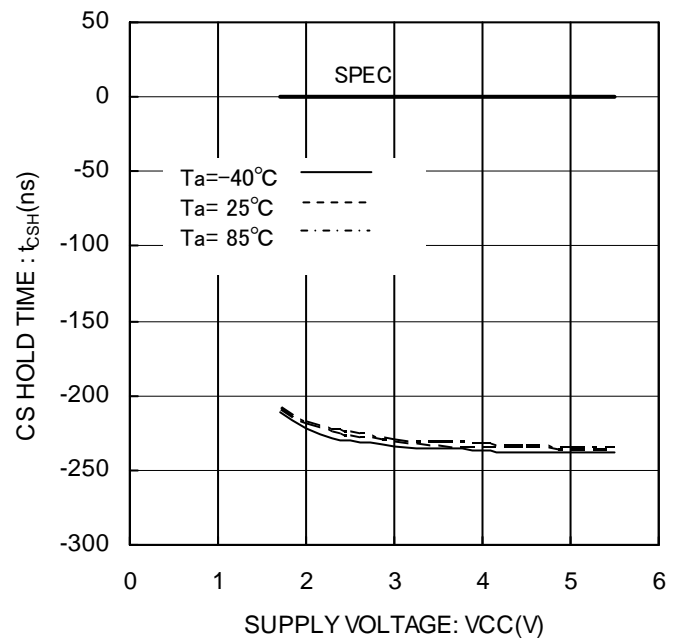
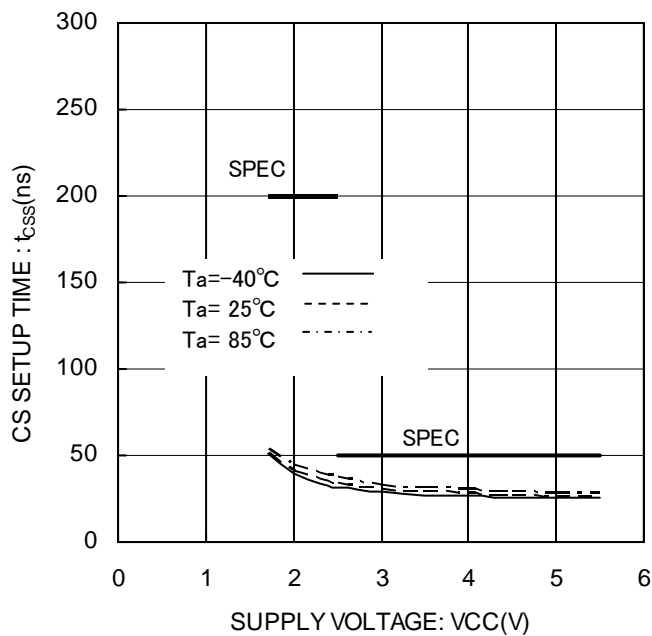
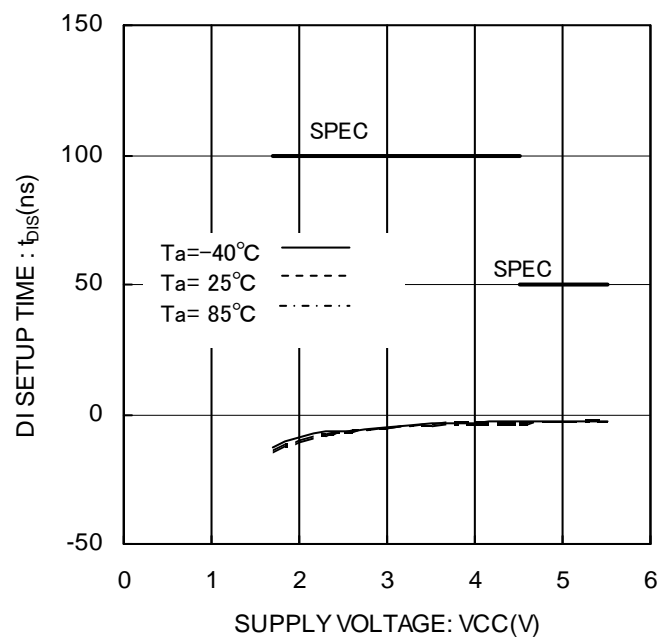


Figure 19. Standby current
 $I_{SB1}(\text{CS}=0\text{V}, \text{ORG}=\text{VCC or OPEN})$

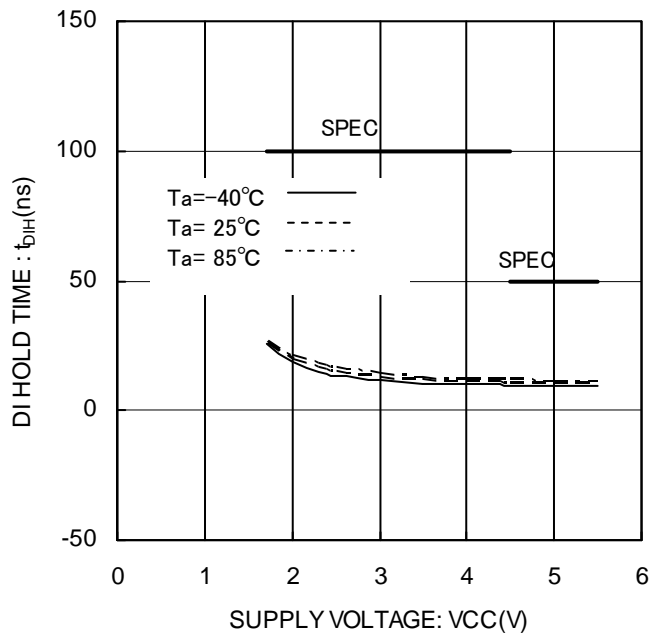
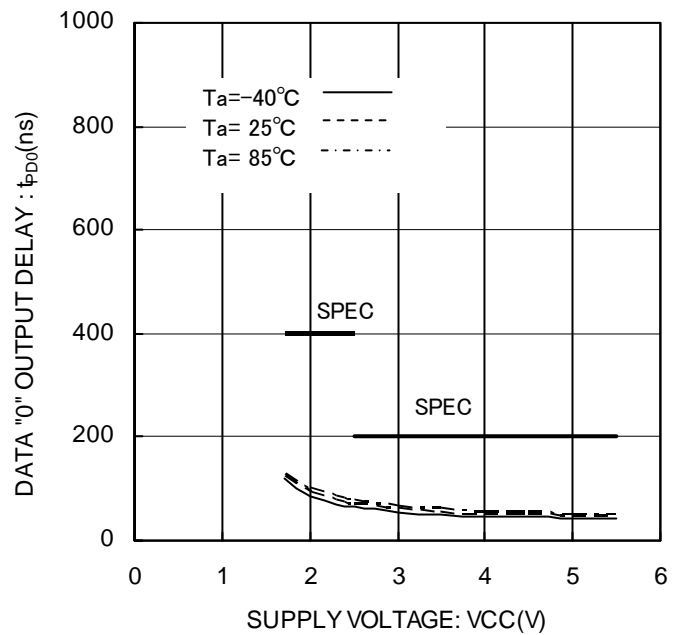
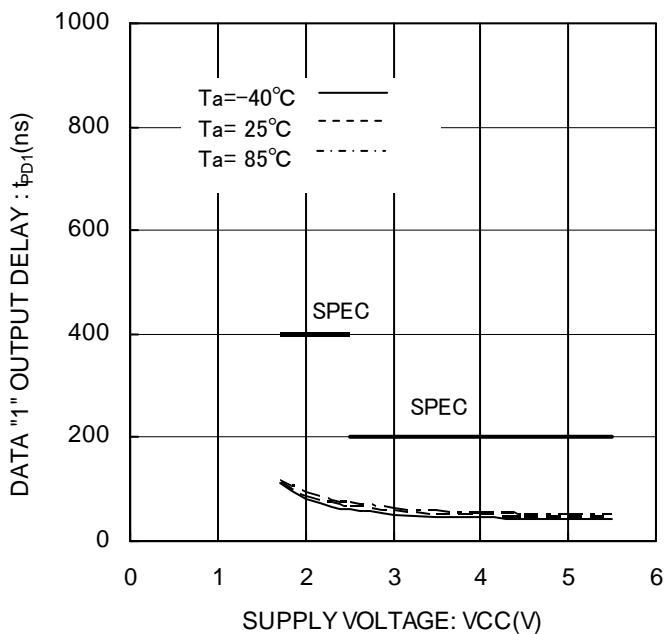
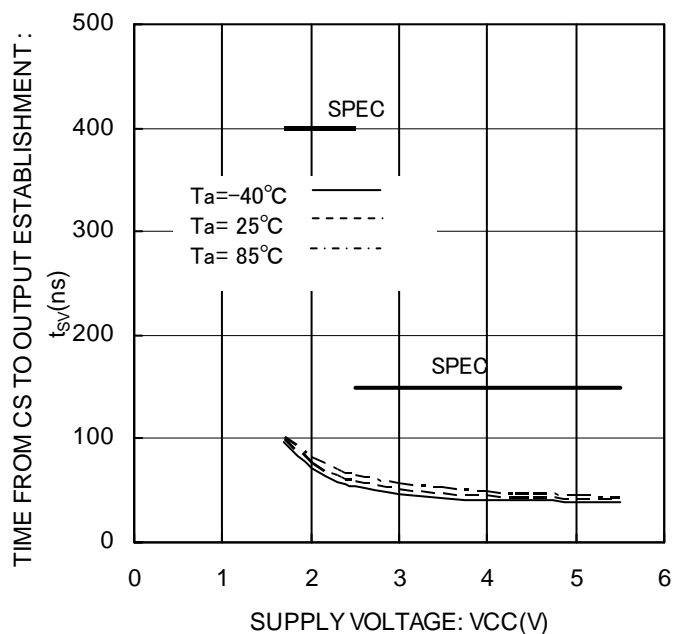
● Typical Performance Curves - Continued

Figure 20. Standby current
 $I_{SB2}(CS=0V, ORG=0V)$ Figure 21. SK frequency f_{SK} Figure 22. SK high time t_{SKH} Figure 23. SK low time t_{SKL}

● Typical Performance Curves - Continued

Figure 24. CS low time t_{cs} Figure 25. CS hold time t_{csh} Figure 26. CS setup time t_{css} Figure 27. DI setup time t_{dis}

● Typical Performance Curves - Continued

Figure 28. DI hold time t_{DIH} Figure 29. Data "0" output delay t_{PD0} Figure 30. Data "1" output delay t_{PD1} Figure 31. Time from CS to output establishment t_{SV}

●Typical Performance Curves - Continued

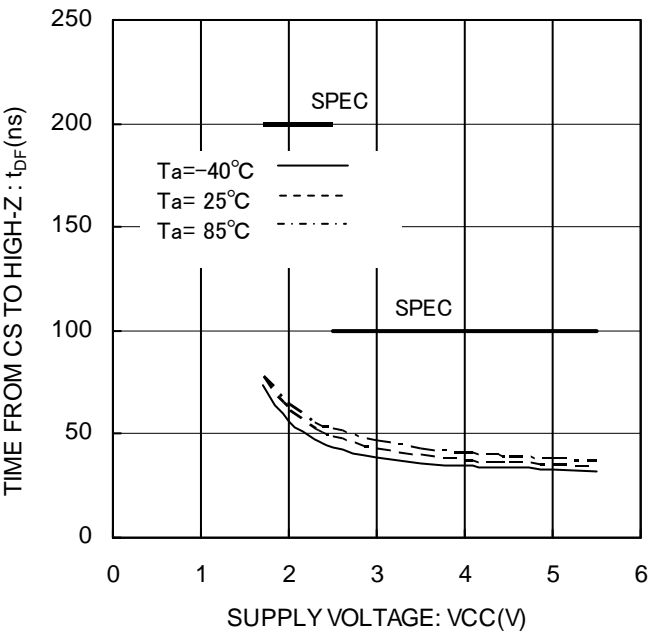


Figure 32. Time from CS to High-Z t_{DF}

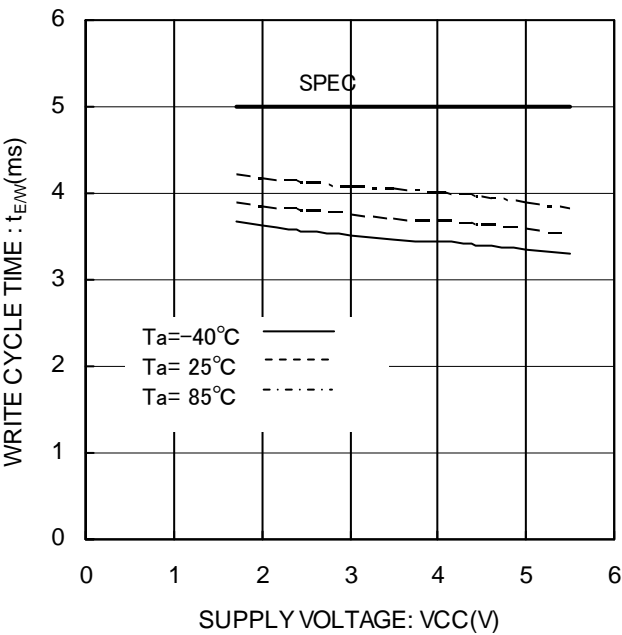


Figure 33. Write cycle time t_{EW}

●Description of operations

Communications of the MicroWire BUS are carried out by SK (serial clock), DI (serial data input), DO (serial data output), and CS (chip select) for device selection.

When to connect one EEPROM to a microcontroller, connect it as shown in Figure 34(a) or Figure 34(b). When to use the input and output common I/O port of the microcontroller, connect DI and DO via a resistor as shown in Figure 34(b) (Refer to pages 21, 22.), and connection by 3 lines is available.

In the case of plural connections, refer to Figure 34 (c).

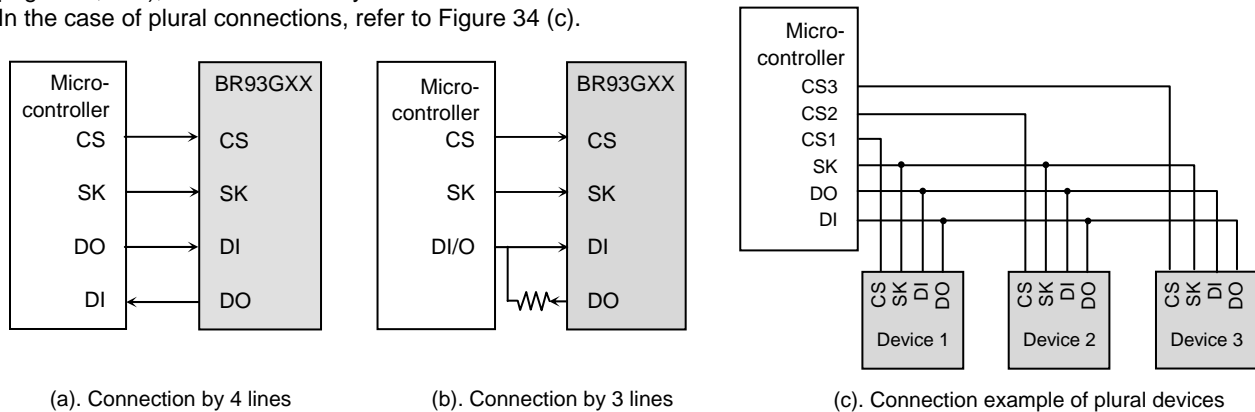


Figure 34. Connection method with microcontroller

Communications of the MicroWire BUS are started by the first "1" input after the rise of CS. This input is called a start bit. After input of the start bit, input ope code, address and data. Address and data are input all in MSB first manners.

"0" input after the rise of CS to the start bit input is all ignored. Therefore, when there is limitation in the bit width of PIO of the microcontroller, input "0" before the start bit input, to control the bit width.

●Command mode

ORG=H or OPEN

Command	Start bit	Ope code	Address	Data MSB of Data(Dx) is D15	Required clocks(n)
			BR93G56-3 MSB of Address(Am) is A7		
Read (READ) *1	1	10	A7,A6,A5,A4,A3,A2,A1,A0	D15~D0(READ DATA)	BR93G56-3:n=27
Write enable (WEN)	1	00	1 1 * * * * *		BR93G56-3:n=11
Write disable (WDS)	1	00	0 0 * * * * *		
Write (WRITE) *2	1	01	A7,A6,A5,A4,A3,A2,A1,A0	D15~D0(WRITE DATA)	BR93G56-3:n=27
Write all (WRAL) *2	1	00	0 1 * * * * *	D15~D0(WRITE DATA)	
Erase (ERASE)	1	11	A7,A6,A5,A4,A3,A2,A1,A0		BR93G56-3:n=11
Erase all (ERAL)	1	00	1 0 * * * * *		

A7 of BR93G56-3 becomes Don't Care.

ORG=L

Command	Start bit	Ope code	Address	Data MSB of Data(Dx) is D7	Required clocks(n)
			BR93G56-3 MSB of Address(Am) is A8		
Read (READ) *1	1	10	A8,A7,A6,A5,A4,A3,A2,A1,A0	D7~D0(READ DATA)	BR93G56-3:n=20
Write enable (WEN)	1	00	1 1 * * * * *		BR93G56-3:n=12
Write disable (WDS)	1	00	0 0 * * * * *		
Write (WRITE) *2	1	01	A8,A7,A6,A5,A4,A3,A2,A1,A0	D7~D0(WRITE DATA)	BR93G56-3:n=20
Write all (WRAL) *2	1	00	0 1 * * * * *	D7~D0(WRITE DATA)	
Erase (ERASE)	1	11	A8,A7,A6,A5,A4,A3,A2,A1,A0		BR93G56-3:n=12
Erase all (ERAL)	1	00	1 0 * * * * *		

A8 of BR93G56-3 becomes Don't Care.

- Input the address and the data in MSB first manners.
- As for *, input either "1" or "0".

*Start bit

Acceptance of all the commands of this IC starts at recognition of the start bit.
The start bit means the first "1" input after the rise of CS.

*1 As for read, by continuous SK clock input after setting the read command, data output of the set address starts, and address data in significant order are sequentially output continuously. (Auto increment function)

*2 For write or write all commands, an internal erase or erase all is included and no separate erase or erase all is needed before write or write all command.

●Timing chart

1) Read cycle (READ)

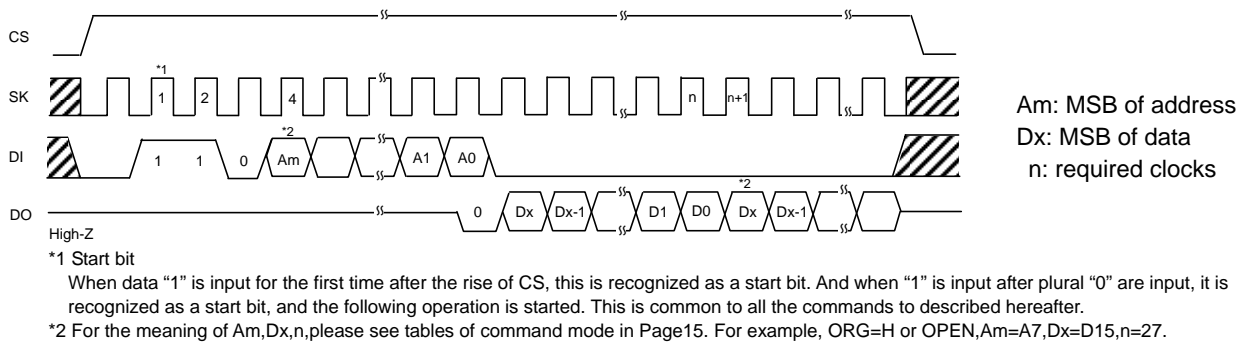


Figure 35. Read cycle

○When the read command is recognized, input address data (16bit or 8bit) is output to serial. And at that moment, at taking A0, in sync with the rise of SK, "0" (dummy bit) is output. And, the following data is output in sync with the rise of SK.

This IC has an address auto increment function which is valid only at read command. This is the function where after the above read execution, by continuously inputting SK clock, the above address data is read sequentially. And, during the auto increment, keep CS at high.

2) Write cycle (WRITE)

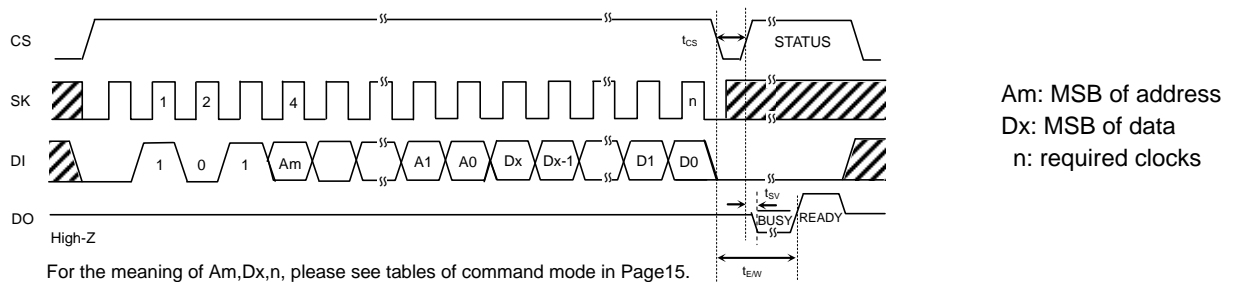


Figure 36. Write cycle

○In this command, input 16bit or 8bit data are written to designated addresses (Am~A0). The actual write starts by the fall of CS of D0 taken SK clock.

When STATUS is not detected (CS=low fixed), make sure Max 5ms time is in conforming with t_{EW} .

When STATUS is detected (CS=high), all commands are not accepted for areas where low (BUSY) is output from DO, therefore, do not input any command.

3) Write all cycle (WRAL)

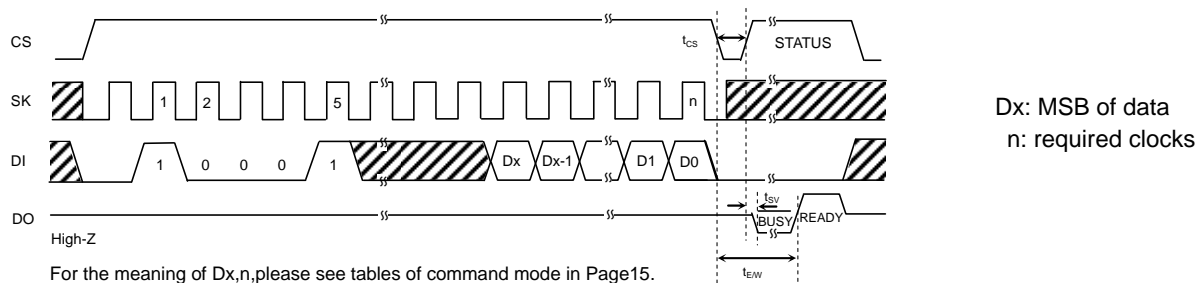


Figure 37. Write all cycle

○In this command, input 16bit or 8bit data is written simultaneously to all addresses. Data is not written continuously per one word but is written in bulk, the write time is only Max. 5ms in conformity with t_{EW} .

In WRAL, STATUS can be detected in the same manner as in WRITE command.

4) Write enable (WEN) / disable (WDS) cycle

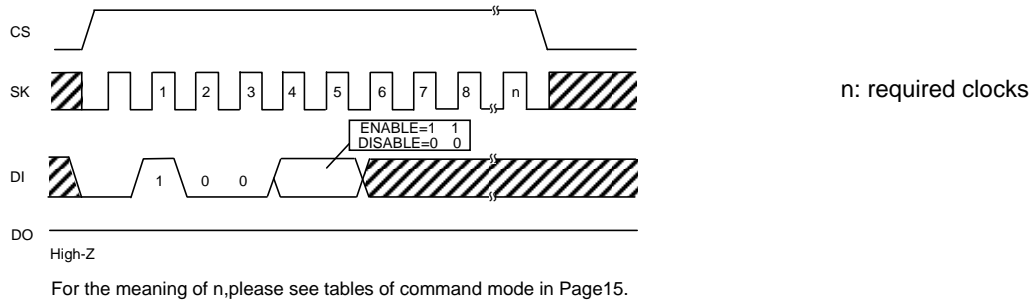


Figure 38. Write enable (WEN) / disable (WDS) cycle

○ At power on, this IC is in write disable status by the internal RESET circuit. Before executing the write command, it is necessary to execute the write enable command. And, once this command is executed, it is valid until the write disable command is executed or the power is turned off. However, the read command is valid irrespective of write enable / disable command. Input to SK after 6 clocks of this command is available by either "1" or "0", but be sure to input it.

○ When the write enable command is executed after power on, write enable status gets in. When the write disable command is executed then, the IC gets in write disable status as same as at power on, and then the write command is canceled thereafter in software manner. However, the read command is executable. In write enable status, even when the write command is input by mistake, write is started. To prevent such a mistake, it is recommended to execute the write disable command after completion of write.

5) Erase cycle (ERASE)

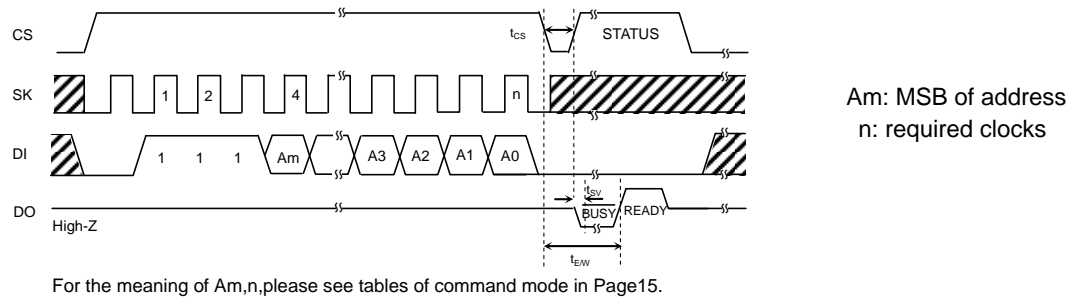


Figure 39. Erase cycle

○ In this command, data of the designated address is made into "1". The data of the designated address becomes "FFFFh or FFh".

Actual ERASE starts at the fall of CS after the fall of A0 taken SK clock.

In ERASE, STATUS can be detected in the same manner as in WRITE command.

6) Erase all cycle (ERAL)

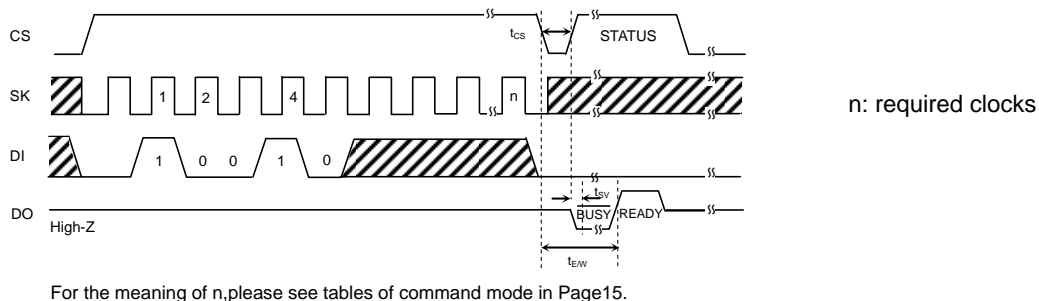


Figure 40. Erase all cycle

○ In this command, data of all addresses is made into "1". Data of all addresses becomes "FFFFh or FFh".

Actual ERASE starts at the fall of CS after the fall of the n-th clock from the start bit input.

In ERAL, STATUS can be detected in the same manner as in WRAL command.

●Application

1)Method to cancel each command

OREAD

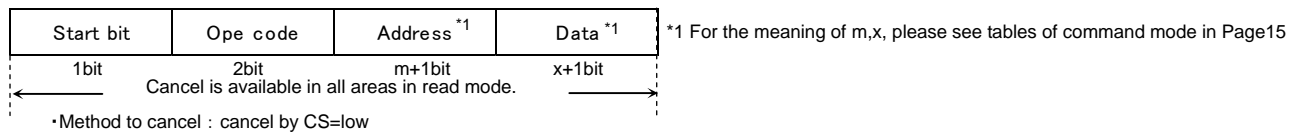


Figure 41. READ cancel available timing

OWRITE,WRAL

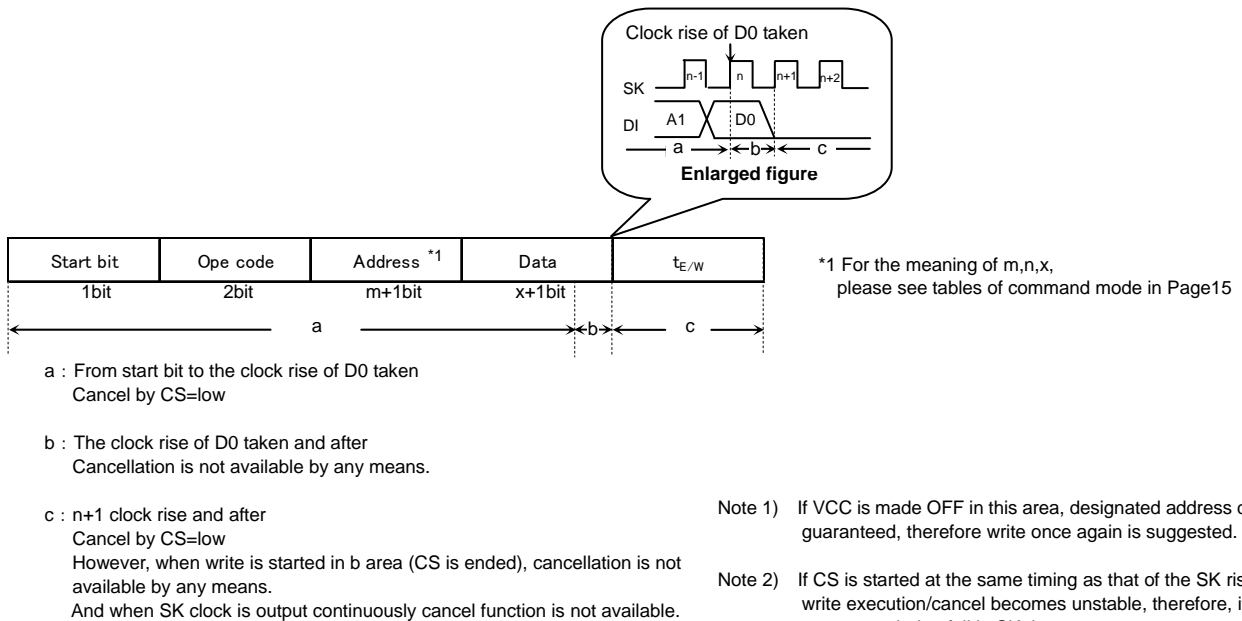


Figure 42. WRITE, WRAL cancel available timing

OERASE, ERAL

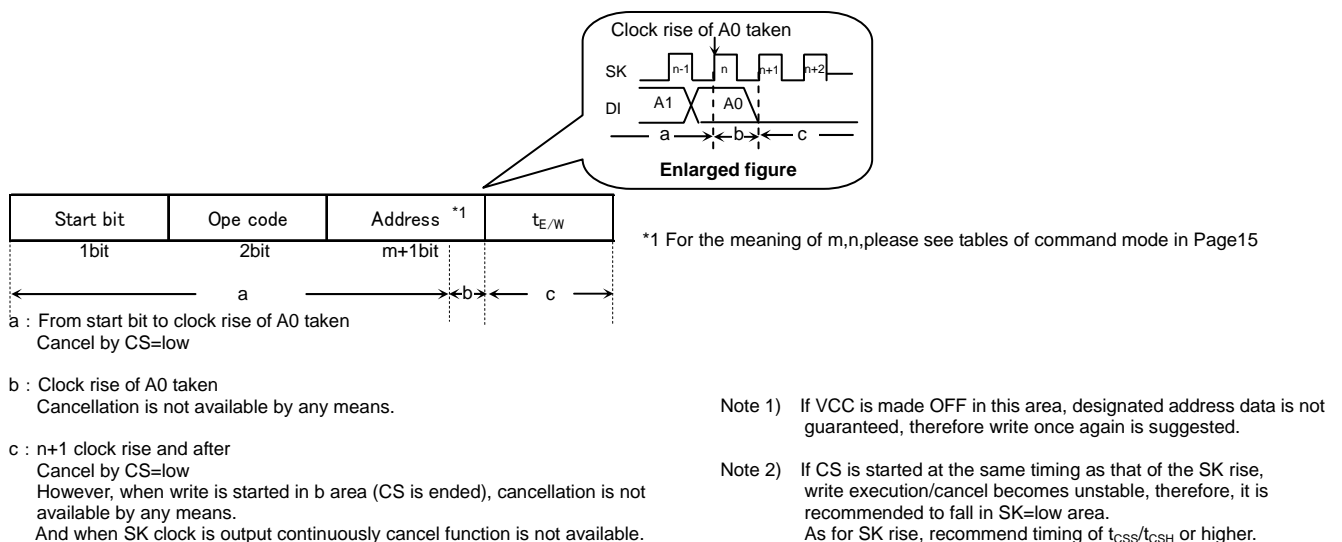


Figure 43. ERASE, ERAL cancel available timing

2) At standby

When CS is low and ORG is high or OPEN, even if SK,DI,DO are low, high or with middle electric potential, current does not over I_{SB1} Max.

When CS is low, even if SK,DI,DO and ORG are low, high or with middle electric potential, current does not over I_{SB2} Max.

3) I/O peripheral circuit

3-1) Pull down CS.

By making CS=low at power ON/OFF, mistake in operation and mistake write are prevented.

OPull down resistance R_{cs} of CS pin

To prevent mistake in operation and mistake write at power ON/OFF, CS pull down resistance is necessary. Select an appropriate value to this resistance value from microcontroller V_{OH} , I_{OH} , and V_{IL} characteristics of this IC.

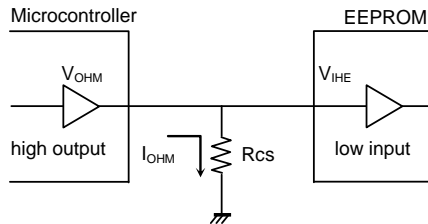


Figure 44. CS pull down resistance

$$R_{cs} \geq \frac{V_{OHM}}{I_{OHM}} \quad \dots \textcircled{1}$$

$$V_{OHM} \geq V_{IHE} \quad \dots \textcircled{2}$$

Example) When $V_{CC}=5V$, $V_{IHE}=2V$, $V_{OHM}=2.4V$, $I_{OHM}=2mA$, from the equation $\textcircled{1}$,

$$R_{cs} \geq \frac{2.4}{2 \times 10^{-3}}$$

$$\therefore R_{cs} \geq 1.2 [k\Omega]$$

With the value of R_{pd} to satisfy the above equation, V_{OHM} becomes 2.4V or higher, and V_{IHE} ($\approx 2.0V$), the equation $\textcircled{2}$ is also satisfied.

- V_{IHE} : EEPROM VIH specifications
- V_{OHM} : Microcontroller V_{OH} specifications
- I_{OHM} : Microcontroller I_{OH} specifications

3-2) DO is available in both pull up and pull down.

Do output always is High-Z except in READY / BUSY STATUS and data output in read command.

Malfunction may occur when High-Z is input to the microcontroller port connected to DO, it is necessary to pull down and pull up DO. When there is no influence upon the microcontroller operations, DO may be OPEN.

If DO is OPEN, and at timing to output STATUS READY, at timing of CS=high, SK=high, DI=high, EEPROM recognizes this as a start bit, resets READY output, and DO=High-Z, therefore, READY signal cannot be detected. To avoid such output, pull up DO pin for improvement.

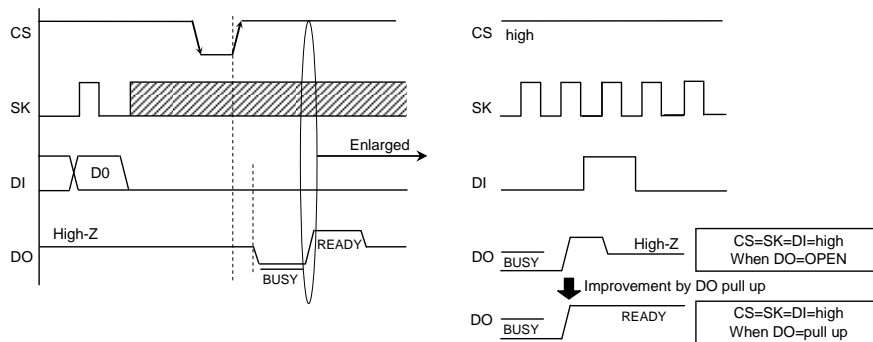


Figure 45. READY output timing at DO=OPEN

OPull up resistance Rpu and pull down resistance Rpd of DO pin

As for pull up and pull down resistance value, select an appropriate value to this resistance value from microcontroller V_{IH} , V_{IL} , and V_{OH} , I_{OH} , V_{OL} , I_{OL} characteristics of this IC.

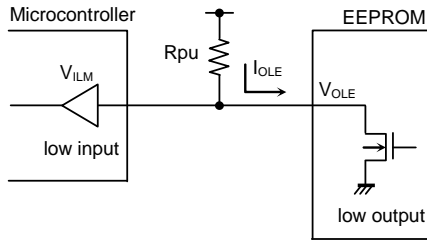


Figure 46. DO pull up resistance

$$R_{pu} \geq \frac{V_{CC} - V_{OLE}}{I_{OLE}} \quad \dots \textcircled{3}$$

$$V_{OLE} \leq V_{ILM} \quad \dots \textcircled{4}$$

Example) When $V_{CC} = 5V$, $V_{OLE} = 0.4V$, $I_{OLE} = 2.1mA$, $V_{ILM} = 0.8V$, from the equation $\textcircled{3}$,

$$R_{pu} \geq \frac{5 - 0.4}{2.1 \times 10^{-3}}$$

$$\therefore R_{pu} \geq 2.2 [k\Omega]$$

With the value of R_{pu} to satisfy the above equation, V_{OLE} becomes 0.4V or below, and with $V_{ILM} (= 0.8V)$, the equation $\textcircled{4}$ is also satisfied.

- V_{OLE} : EEPROM V_{OL} specifications
- I_{OLE} : EEPROM I_{OL} specifications
- V_{ILM} : Microcontroller V_{IL} specifications

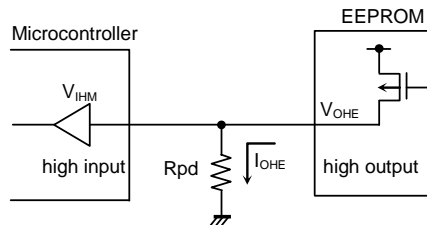


Figure 47. DO pull down resistance

$$R_{pd} \geq \frac{V_{OHE}}{I_{OHE}} \quad \dots \textcircled{5}$$

$$V_{OHE} \geq V_{IHM} \quad \dots \textcircled{6}$$

Example) When $V_{CC} = 5V$, $V_{OHE} = V_{CC} - 0.2V$, $I_{OHE} = 0.1mA$, $V_{IHM} = V_{CC} \times 0.7V$ from the equation $\textcircled{5}$,

$$R_{pd} \geq \frac{5 - 0.2}{0.1 \times 10^{-3}}$$

$$\therefore R_{pd} \geq 48 [k\Omega]$$

With the value of R_{pd} to satisfy the above equation, V_{OHE} becomes 2.4V or below, and with $V_{IHM} (= 3.5V)$, the equation $\textcircled{6}$ is also satisfied.

- V_{OHE} : EEPROM V_{OH} specifications
- I_{OHE} : EEPROM I_{OH} specifications
- V_{IHM} : Microcontroller V_{IH} specifications

OR \overline{B} / \overline{BUSY} STATUS display (DO terminal)

This display outputs the internal STATUS signal. When CS is started after t_{CS} from CS fall after write command input, high or low is output.

R/\overline{B} display = low (\overline{BUSY}) = write under execution

(DO STATUS) After the timer circuit in the IC works and creates the period of t_{EW} , this timer circuit completes automatically. And the memory cell is written in the period of t_{EW} , and during this period, other command is not accepted.

R/\overline{B} display = high (READY) = command wait STATUS

(DO STATUS) After t_{EW} (max.5ms) the following command is accepted. Therefore, CS=high in the period of t_{EW} , and If signals are input in SK, DI, malfunction may occur, therefore, DI=low in the area CS=high. (Especially, in the case of shared input port, attention is required.)

*Do not input any command while STATUS signal is output. Command input in \overline{BUSY} area is cancelled, but command input in READY area is accepted. Therefore, STATUS READY output is cancelled, and malfunction and mistake write may occur.

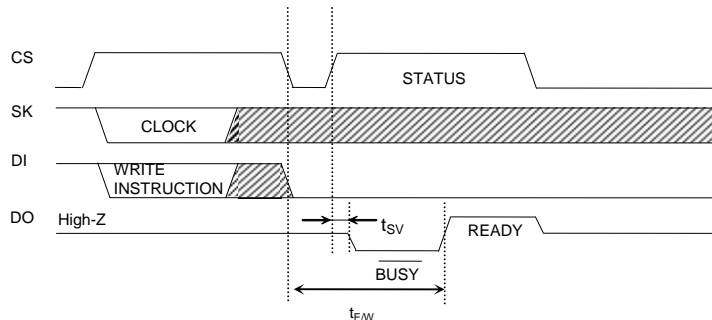


Figure 48. READY/ \overline{BUSY} STATUS output timing chart

4) When to directly connect DI and DO

This IC has independent input terminal DI and output terminal DO, and separate signals are handled on timing chart, meanwhile, by inserting a resistance R between these DI and DO terminals, it is possible to carry out control by 1 control line.

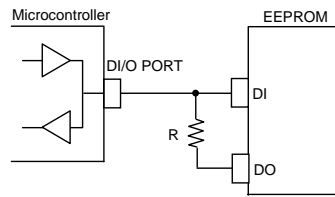


Figure 49. DI, DO control line common connection

○Data collision of microcontroller DI/O output and DO output and feedback of DO output to DI input of EEPROM.

Drive from the microcontroller DI/O output to DI input of EEPROM on I/O timing, and output signal from DO output of EEPROM occur at the same time in the following points.

4-1) 1 clock cycle to take in A0 address data at read command

Dummy bit "0" is output to DO terminal.

→When address data A0 = "1" input, through current route occurs.

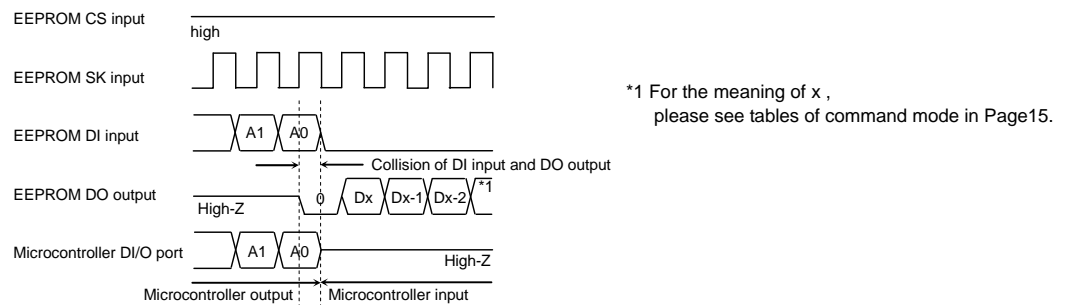


Figure 50. Collision timing at read data output at DI, DO direct connection

4-2) Timing of CS = high after write command. DO terminal in READY / $\overline{\text{BUSY}}$ function output.

When the next start bit input is recognized, High-Z gets in.

→Especially, at command input after write, when CS input is started with microcontroller DI/O output low, READY output high is output from DO terminal, and through current route occurs.

Feedback input at timing of these (4-1) and (4-2) does not cause disorder in basic operations, if resistance R is inserted.

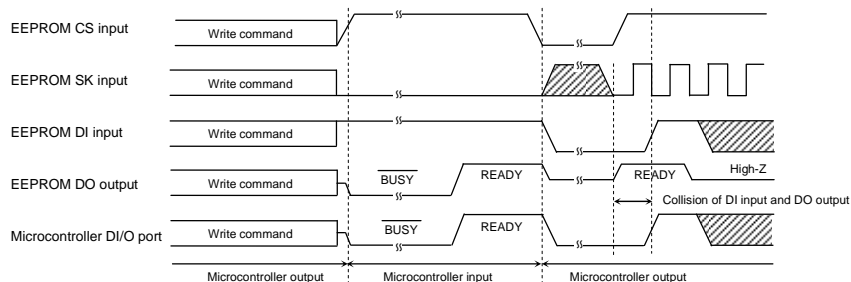


Figure 51. Collision timing at DI, DO direct connection

Note) As for the case (4-2), attention must be paid to the following.

When STATUS READY is output, DO and DI are shared, DI=high and the microcontroller DI/O=High-Z or the microcontroller DI/O=high, if SK clock is input, DO output is input to DI and is recognized as a start bit, and malfunction may occur. As a method to avoid malfunction, at STATUS READY output, set SK=low, or start CS within 4 clocks after high of READY signal is output.

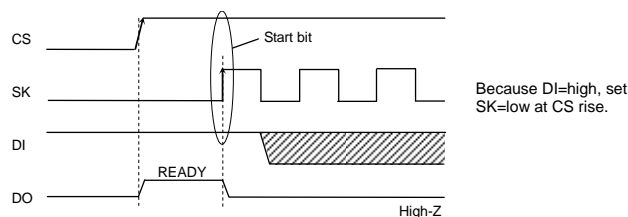


Figure 52 Start bit input timing at DI, DO direct connection

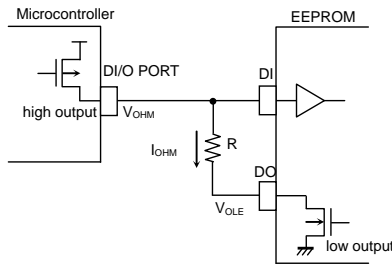
○ Selection of resistance value R

The resistance R becomes through current limit resistance at data collision. When through current flows, noises of power source line and instantaneous stop of power source may occur. When allowable through current is defined as I, the following relation should be satisfied. Determine allowable current amount in consideration of impedance and so forth of power source line in set. And insert resistance R, and set the value R to satisfy EEPROM input level V_{IH}/V_{IL} even under influence of voltage decline owing to leak current and so forth. Insertion of R will not cause any influence upon basic operations.

4-3) Address data A0 = "1" input, dummy bit "0" output timing

(When microcontroller DI/O output is high, EEPROM DO outputs low, and high is input to DI)

- Make the through current to EEPROM 10mA or below.
- See to it that the level V_{IH} of EEPROM should satisfy the following.



Conditions

$$V_{IHE} \leq I_{OHM} \times R + V_{OLE}$$

At this moment, if $V_{OLE}=0V$,

$$V_{IHE} \leq I_{OHM} \times R$$

$$\therefore R \geq \frac{V_{IHE}}{I_{OHM}} \quad \dots \textcircled{7}$$

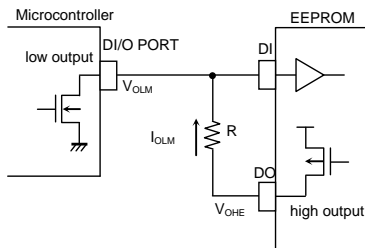
- V_{IHE} : EEPROM V_{IH} specifications
- V_{OLE} : EEPROM V_{OL} specifications
- I_{OHM} : Microcontroller I_{OH} specifications

Figure 53. Circuit at DI, DO direct connection (Microcontroller DI/O high output, EEPROM low output)

4-4) DO STATUS READY output timing

(When the microcontroller DI/O is low, EEPROM DO output high, and low is input to DI)

- Set the EEPROM input level V_{IL} so as to satisfy the following.



Conditions

$$V_{ILE} \geq V_{OHE} - I_{OLM} \times R$$

As this moment, $V_{OHE}=V_{CC}$

$$V_{ILE} \geq V_{CC} - I_{OLM} \times R$$

$$\therefore R \geq \frac{V_{CC} - V_{ILE}}{I_{OLM}} \quad \dots \textcircled{8}$$

- V_{ILE} : EEPROM V_{IL} specifications
- V_{OHE} : EEPROM V_{OH} specifications
- I_{OLM} : Microcontroller I_{OL} specifications

Example) When $V_{CC}=5V$, $V_{OHM}=5V$, $I_{OHM}=0.4mA$, $V_{OLM}=5V$, $I_{OLM}=0.4mA$,

From the equation ⑦,

$$R \geq \frac{V_{IHE}}{I_{OHM}}$$

$$R \geq \frac{3.5}{0.4 \times 10^{-3}}$$

$$\therefore R \geq 8.75 \text{ [k}\Omega\text{]} \quad \dots \textcircled{9}$$

From the equation ⑧,

$$R \geq \frac{V_{CC} - V_{ILE}}{I_{OLM}}$$

$$R \geq \frac{5 - 1.5}{2.1 \times 10^{-3}}$$

$$\therefore R \geq 1.67 \text{ [k}\Omega\text{]} \quad \dots \textcircled{10}$$

Therefore, from the equations ⑨ and ⑩,

$$\therefore R \geq 8.75 \text{ [k}\Omega\text{]}$$

Figure 54. Circuit at DI, DO direct connection (Microcontroller DI/O low output, EEPROM high output)

5) I/O equivalence circuit

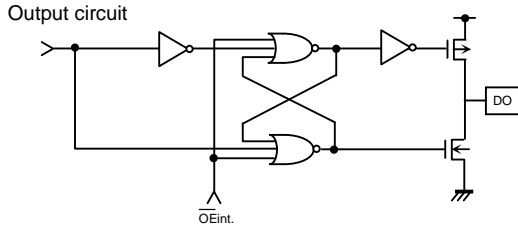


Figure 55. Output circuit (DO)

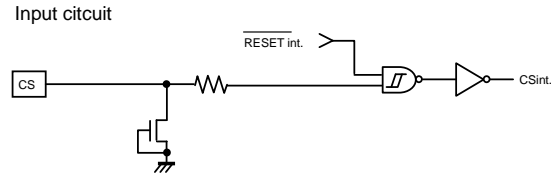


Figure 56. Input circuit (CS)

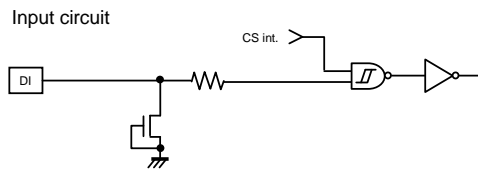


Figure 57. Input circuit (DI)

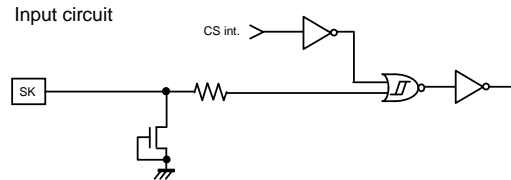


Figure 58. Input circuit (SK)

6) Power-Up/Down conditions

○At power ON/OFF, set CS low.

When CS is high, this IC gets in input accept status (active). If power is turned on in this status, noises and the likes may cause malfunction, mistake write or so. To prevent these, at power ON, set CS low. (When CS is in low status all inputs are cancelled.) And at power decline, owing to power line capacity and so forth, low power status may continue long. At this case too, owing to the same reason, malfunction, mistake write may occur, therefore, at power OFF too, set CS low.

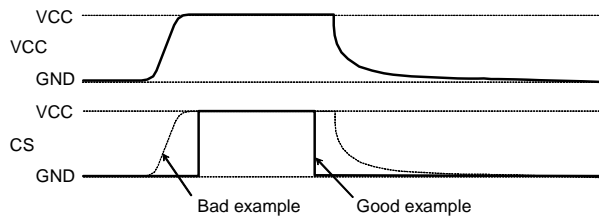


Figure 59. Timing at power ON/OFF

(Bad example) CS pin is pulled up to VCC

In this case, CS becomes high (active status), and EEPROM may have malfunction, mistake write owing to noise and the likes.
Even when CS input is High-Z, the status becomes like this case, which please note.

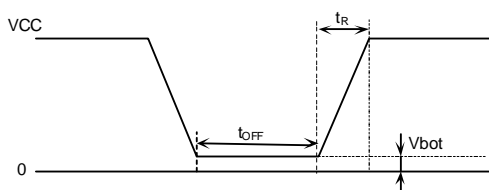
(Good example) It is low at power ON/OFF.

Set 10ms or higher to recharge at power OFF.
When power is turned on without observing this condition, IC internal circuit may not be reset, which please note.

OPOR circuit

This IC has a POR (Power On Reset) circuit as a mistake write countermeasure. After POR operation, it gets in write disable status. The POR circuit is valid only when power is ON, and does not work when power is OFF. However, if CS is high at power ON/OFF, it may become write enable status owing to noises and the likes. For secure operations, observe the following conditions.

1. Set CS=low
2. Turn on power so as to satisfy the recommended conditions of t_R , t_{OFF} , V_{bot} for POR circuit operation.



Recommended conditions of t_R , t_{OFF} , V_{bot}

t_R	t_{OFF}	V_{bot}
10ms or below	10ms or higher	0.3V or below
100ms or below	10ms or higher	0.2V or below

Figure 60. Rise waveform diagram

OLVCC circuit

LVCC (VCC-Lockout) circuit prevents data rewrite operation at low power, and prevents wrong write.

At LVCC voltage (Typ.=1.2V) or below, it prevent data rewrite

7) Noise countermeasures

○ VCC noise (bypass capacitor)

When noise or surge gets in the power source line, malfunction may occur, therefore, for removing these, it is recommended to attach a bypass capacitor (0.1μF) between IC VCC and GND. At that moment, attach it as close to IC as possible. And, it is also recommended to attach a bypass capacitor between board VCC and GND.

○ SK noise

When the rise time of SK is long, and a certain degree or more of noise exists, malfunction may occur owing to clock bit displacement. To avoid this, a Schmitt trigger circuit is built in SK input. The hysteresis width of this circuit is set about 0.2V, if noises exist at SK input, set the noise amplitude 0.2Vp-p or below. And it is recommended to set the rise time of SK 100ns or below. In the case when the rise time is 100ns or higher, take sufficient noise countermeasures. Make the clock rise, fall time as small as possible.

●Operational Notes

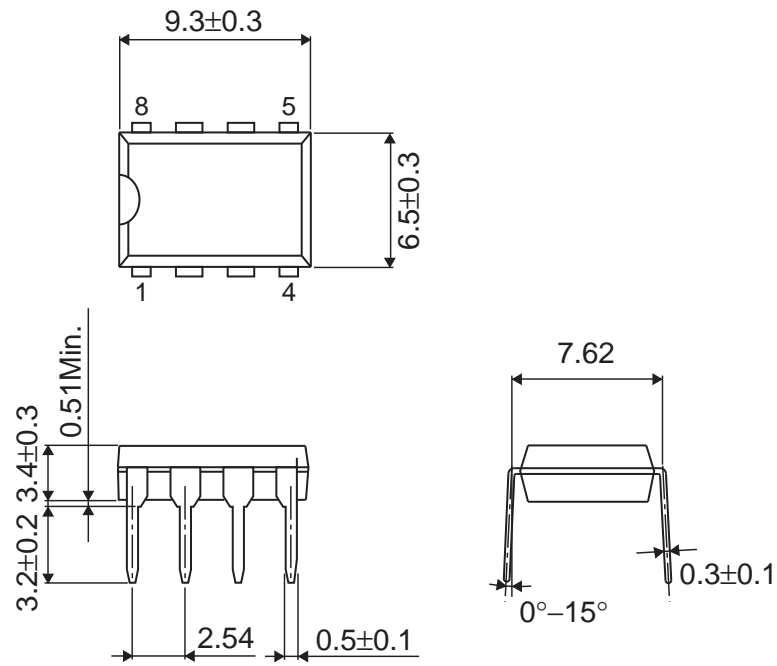
- (1) Described numeric values and data are design representative values, and the values are not guaranteed.
- (2) We believe that application circuit examples are recommendable, however, in actual use, confirm characteristics further sufficiently. In the case of use by changing the fixed number of external parts, make your decision with sufficient margin in consideration of static characteristics and transition characteristics and fluctuations of external parts and our LSI.
- (3) Absolute Maximum Ratings
If the absolute maximum ratings such as supply voltage and operating temperature and so forth are exceeded, LSI may be destructed. Do not impress voltage and temperature exceeding the absolute maximum ratings. In the case of fear exceeding the absolute maximum ratings, take physical safety countermeasures such as fuses, and see to it that conditions exceeding the absolute maximum ratings should not be impressed to LSI.
- (4) GND electric potential
Set the voltage of GND terminal lowest at any operating condition. Make sure that each terminal voltage is not lower than that of GND terminal in consideration of transition status.
- (5) Heat design
In consideration of allowable loss in actual use condition, carry out heat design with sufficient margin.
- (6) Terminal to terminal short circuit and wrong packaging
When to package LSI onto a board, pay sufficient attention to LSI direction and displacement. Wrong packaging may destruct LSI. And in the case of pin short between LSI terminals and terminals, terminals and power source, terminals and GND owing to unconnect use, LSI may be destructed.
- (7) Using this LSI in a strong electromagnetic field may cause malfunction, therefore, evaluate the design sufficiently.

● Part numbering

B	R	9	3	G	5	6	x	x	x	—	3	x																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																																				
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●Physical Dimensions Tape and Reel information

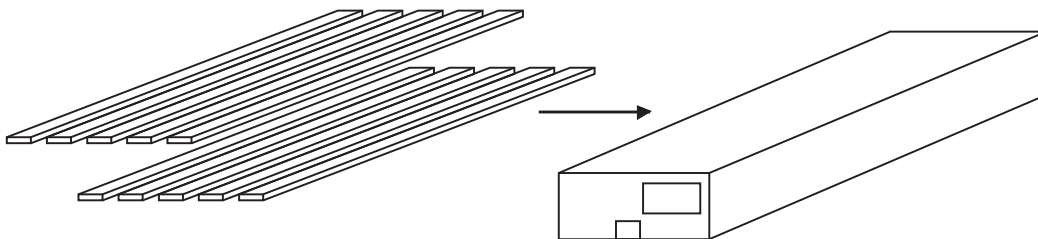
DIP-T8



(Unit : mm)

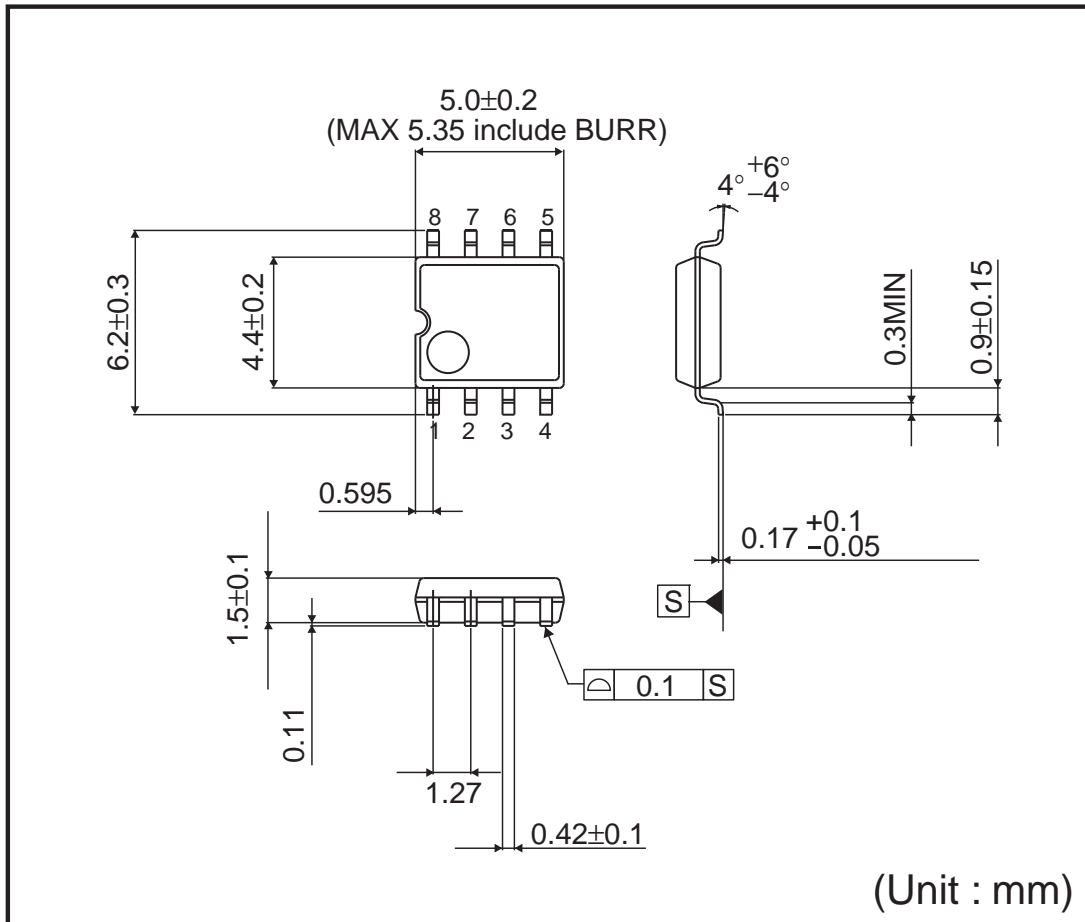
<Tape and Reel information>

Container	Tube
Quantity	2000pcs
Direction of feed	Direction of products is fixed in a container tube



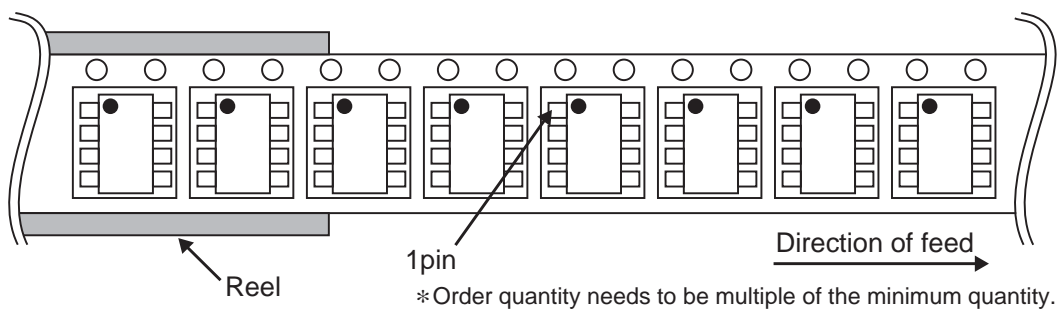
* Order quantity needs to be multiple of the minimum quantity.

SOP8

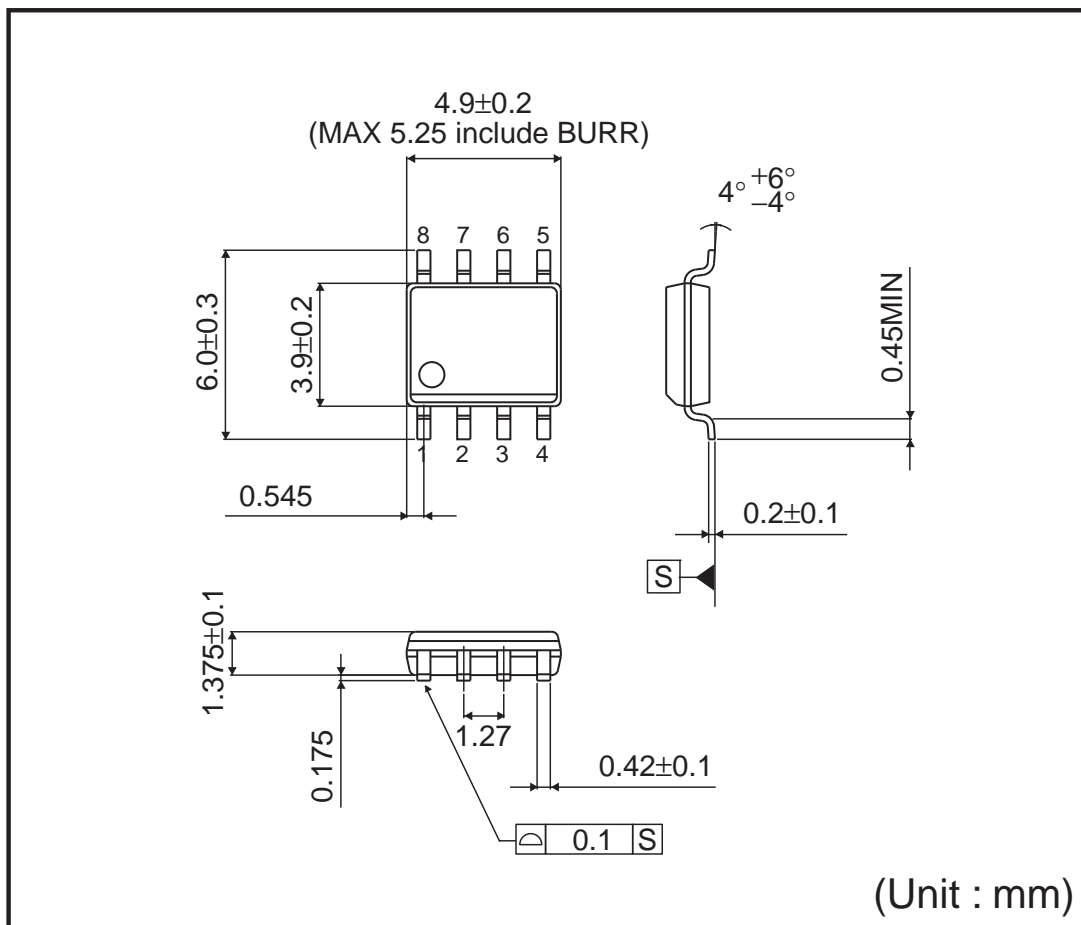


<Tape and Reel information>

Tape	Embossed carrier tape
Quantity	2500pcs
Direction of feed	E2 (The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand)

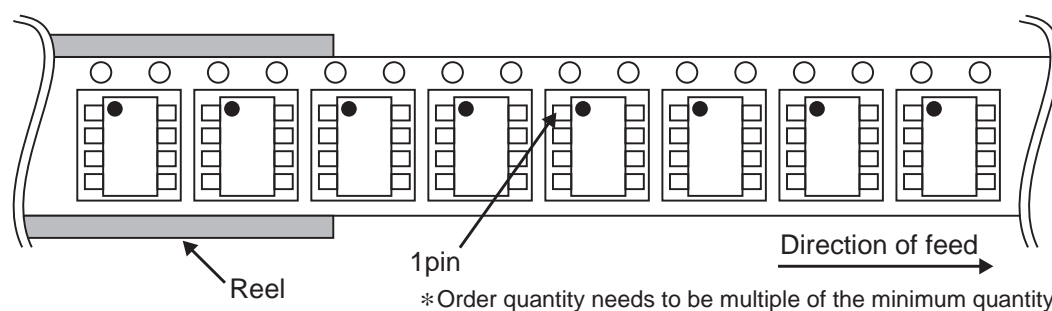


SOP-J8



<Tape and Reel information>

Tape	Embossed carrier tape
Quantity	2500pcs
Direction of feed	E2 (The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand)

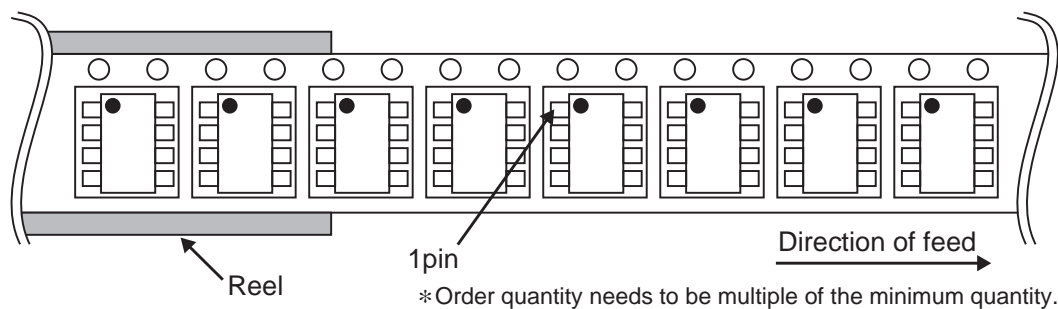


SSOP-B8

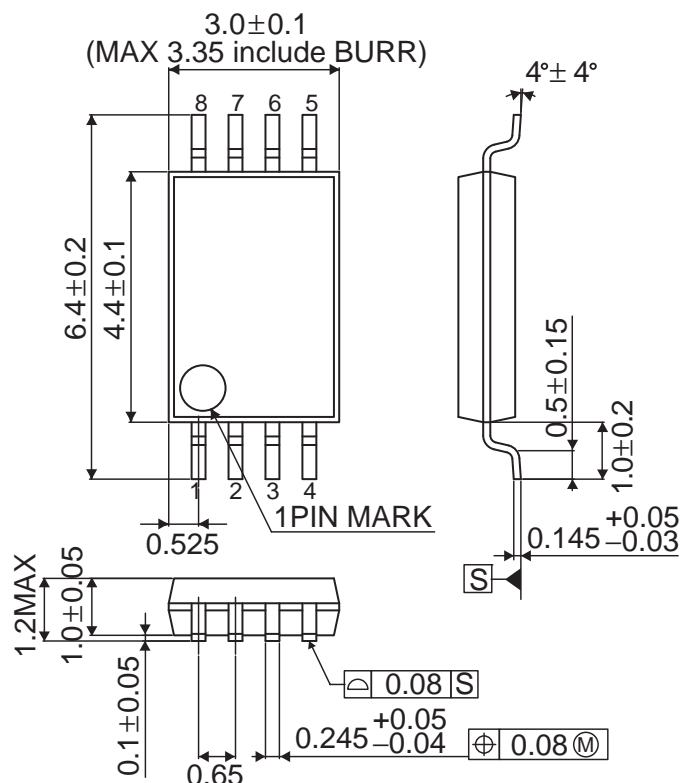


<Tape and Reel information>

Tape	Embossed carrier tape
Quantity	2500pcs
Direction of feed	E2 (The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand)



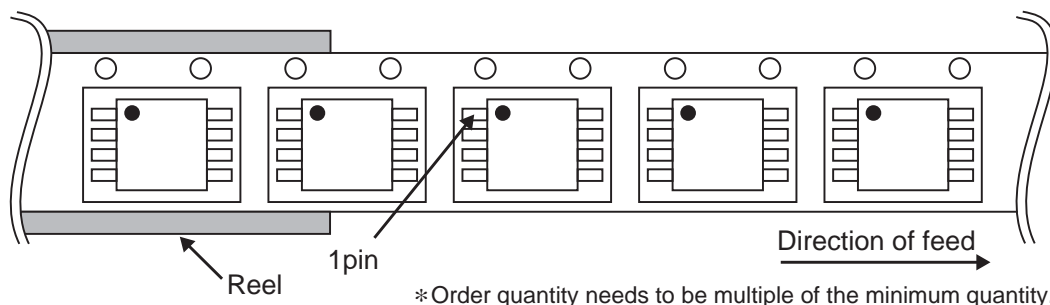
TSSOP-B8



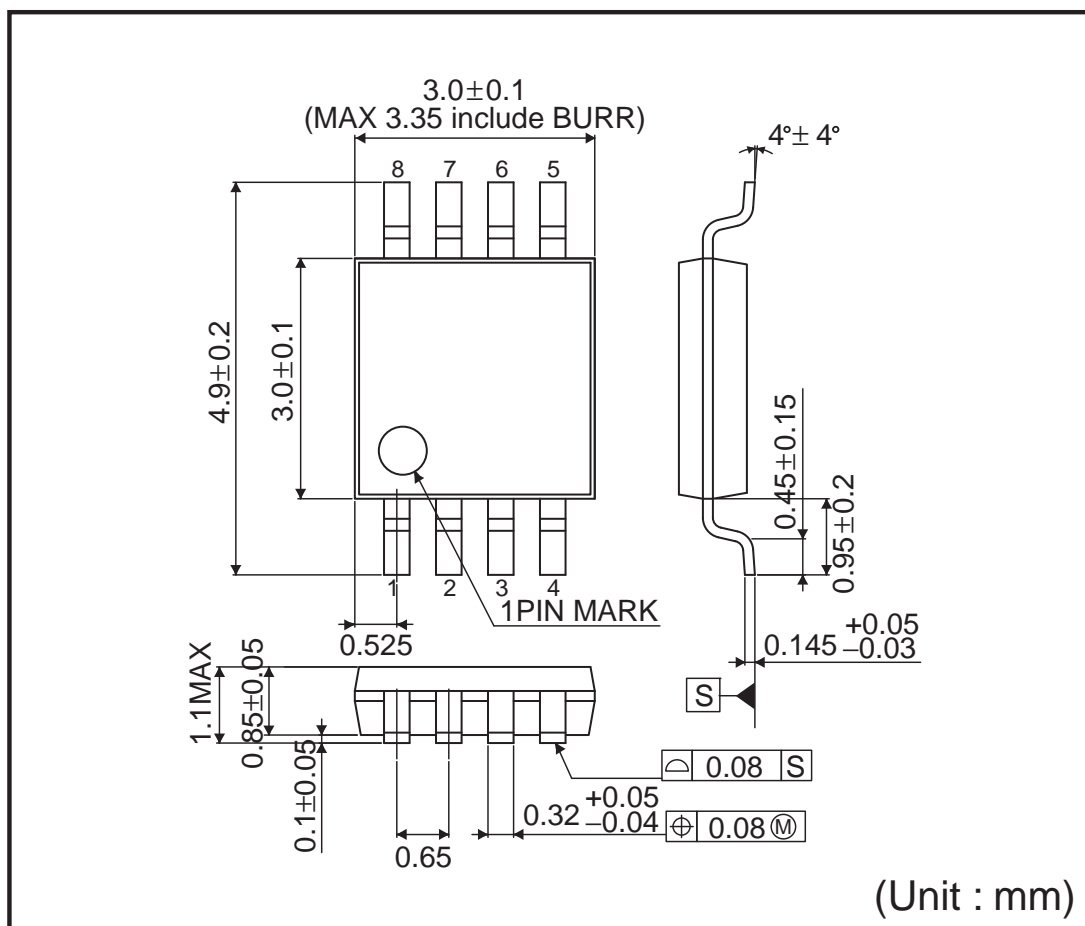
(Unit : mm)

<Tape and Reel information>

Tape	Embossed carrier tape
Quantity	3000pcs
Direction of feed	E2 (The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand)

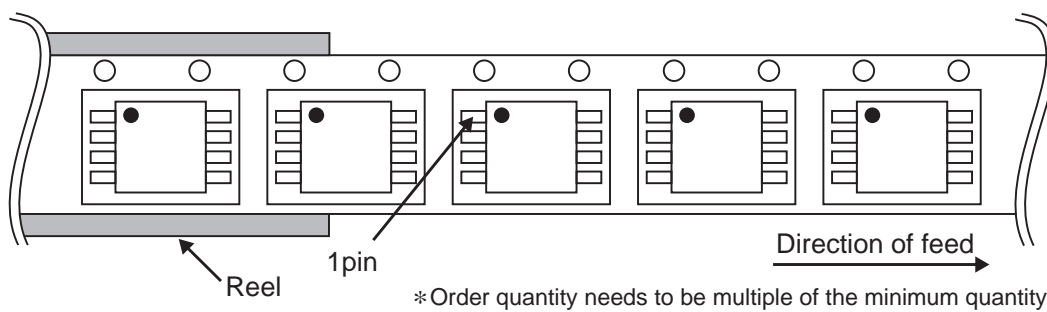


TSSOP-B8J

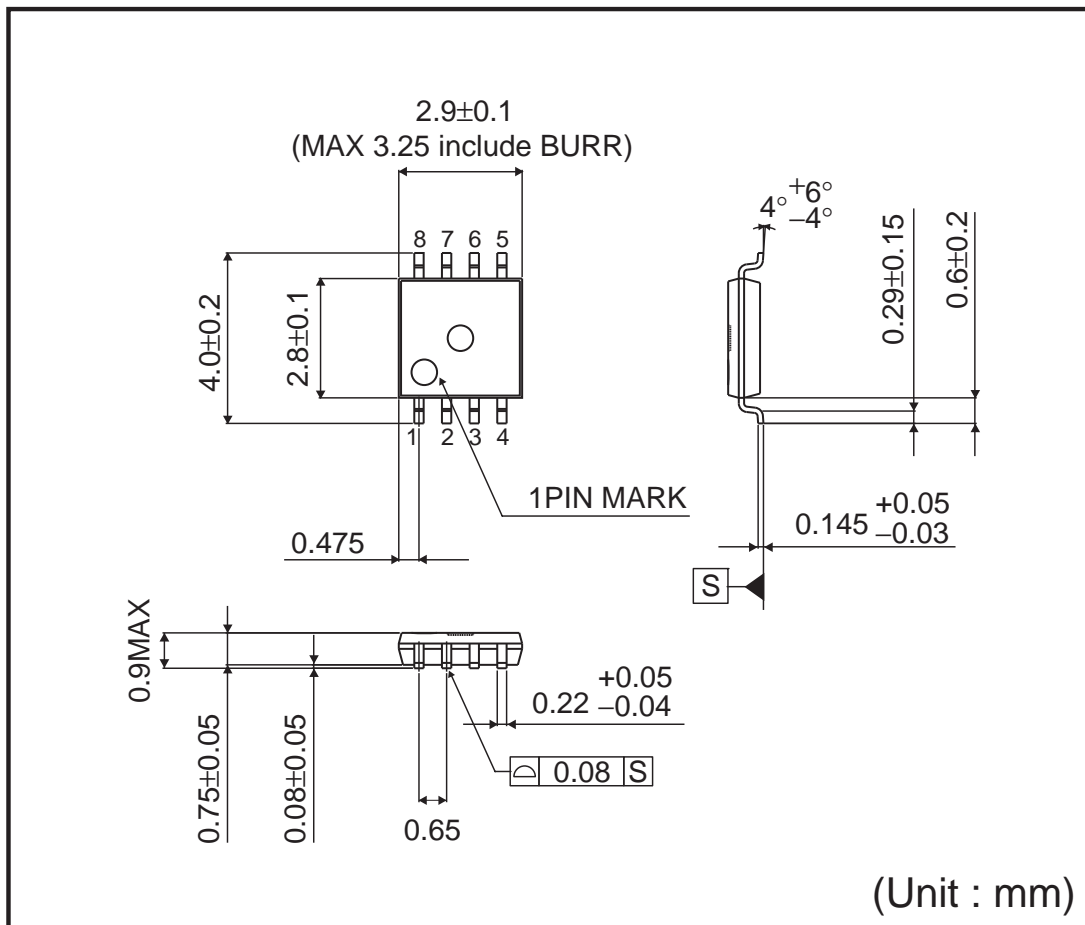


<Tape and Reel information>

Tape	Embossed carrier tape
Quantity	2500pcs
Direction of feed	E2 (The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand)

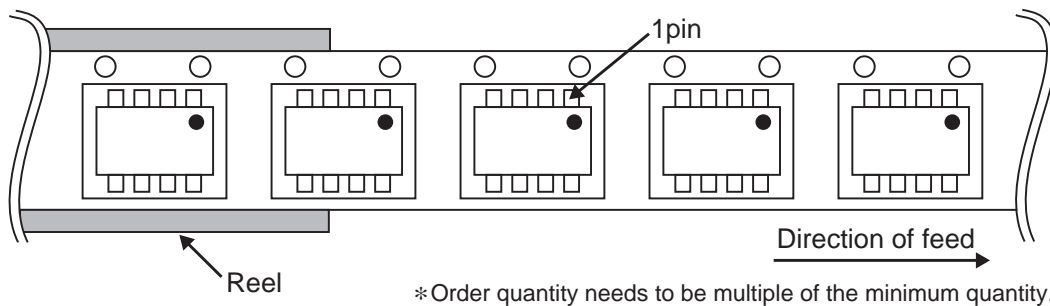


MSOP8

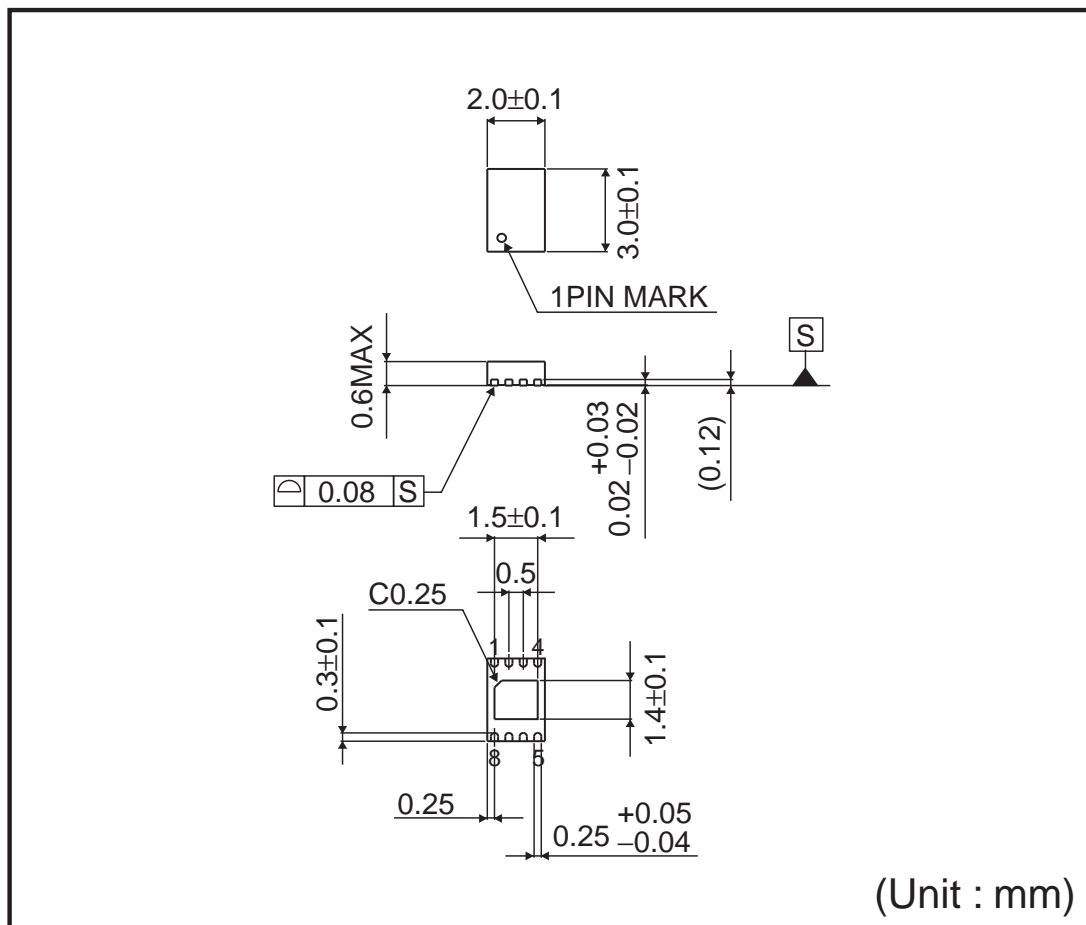


<Tape and Reel information>

Tape	Embossed carrier tape
Quantity	3000pcs
Direction of feed	TR (The direction is the 1pin of product is at the upper right when you hold reel on the left hand and you pull out the tape on the right hand)



VSON008X2030



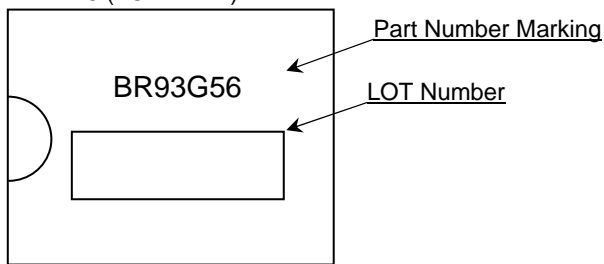
<Tape and Reel information>

Tape	Embossed carrier tape
Quantity	4000pcs
Direction of feed	TR (The direction is the 1 pin of product is at the upper right when you hold reel on the left hand and you pull out the tape on the right hand)

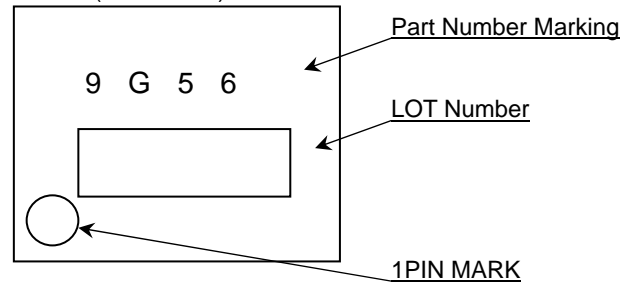


●Marking Diagrams

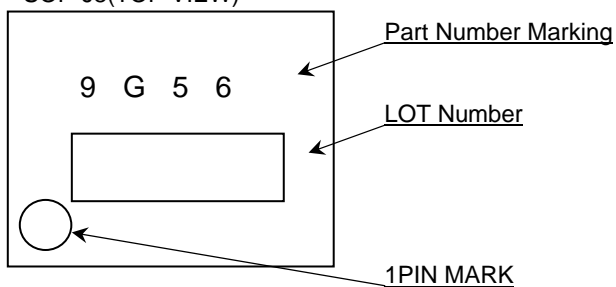
DIP-T8 (TOP VIEW)



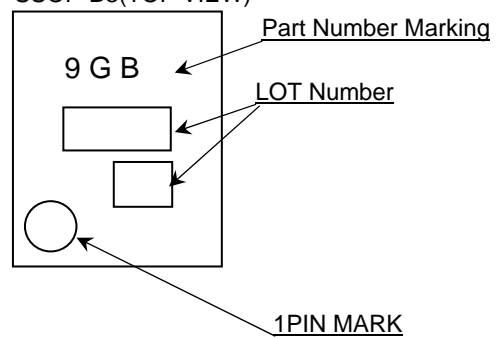
SOP8(TOP VIEW)



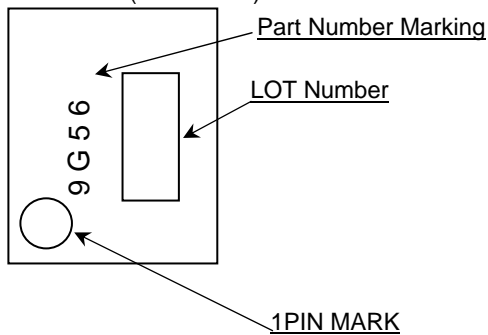
SOP-J8(TOP VIEW)



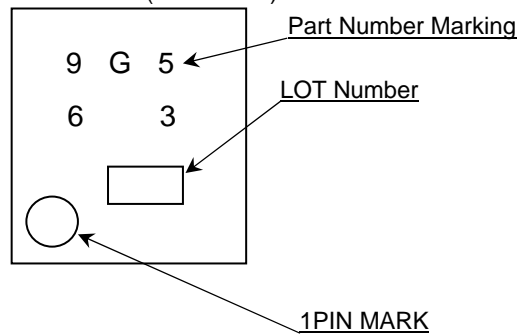
SSOP-B8(TOP VIEW)



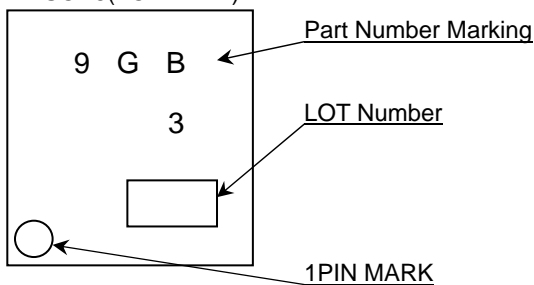
TSSOP-B8(TOP VIEW)



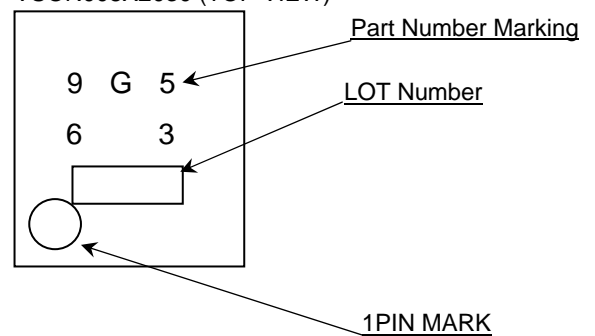
TSSOP-B8J(TOP VIEW)



MSOP8(TOP VIEW)



VSON008X2030 (TOP VIEW)



●Revision History

Date	Revision	Changes
22.Aug.2012	001	New Release
07.Jan.2013	002	Update some English words and sentences' descriptions. Delete "Status of this document" in page25. Delete "Lineup" after "Part numbering " in page26

Notice

Precaution on using ROHM Products

- Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment ^(Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASS III	CLASS III	CLASS II b	CLASS III
CLASS IV		CLASS III	

- ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
 - Installation of protection circuits or other protective devices to improve system safety
 - Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc. prior to use, must be necessary:
 - Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
 - Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - Sealing or coating our Products with resin or other coating materials
 - Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - Use of the Products in places subject to dew condensation
- The Products are not subject to radiation-proof design.
- Please verify and confirm characteristics of the final or mounted products in using the Products.
- In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of ionizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

QR code printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since our Products might fall under controlled goods prescribed by the applicable foreign exchange and foreign trade act, please consult with ROHM representative in case of export.

Precaution Regarding Intellectual Property Rights

1. All information and data including but not limited to application example contained in this document is for reference only. ROHM does not warrant that foregoing information or data will not infringe any intellectual property rights or any other rights of any third party regarding such information or data. ROHM shall not be in any way responsible or liable for infringement of any intellectual property rights or other damages arising from use of such information or data.:
2. No license, expressly or implied, is granted hereby under any intellectual property rights or other rights of ROHM or any third parties with respect to the information contained in this document.

Other Precaution

1. This document may not be reprinted or reproduced, in whole or in part, without prior written consent of ROHM.
2. The Products may not be disassembled, converted, modified, reproduced or otherwise changed without prior written consent of ROHM.
3. In no event shall you use in any way whatsoever the Products and the related technical information contained in the Products or this document for any military purposes, including but not limited to, the development of mass-destruction weapons.
4. The proper names of companies or products described in this document are trademarks or registered trademarks of ROHM, its affiliated companies or third parties.

General Precaution

1. Before you use our Products, you are requested to carefully read this document and fully understand its contents. ROHM shall not be in any way responsible or liable for failure, malfunction or accident arising from the use of any ROHM's Products against warning, caution or note contained in this document.
2. All information contained in this document is current as of the issuing date and subject to change without any prior notice. Before purchasing or using ROHM's Products, please confirm the latest information with a ROHM sales representative.
3. The information contained in this document is provided on an "as is" basis and ROHM does not warrant that all information contained in this document is accurate and/or error-free. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties resulting from inaccuracy or errors of or concerning such information.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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